

## RL78/G1P

R01DS0371EJ0100

RENESAS MCU

Rev.1.00

Nov 29, 2019

True low-power platform (66  $\mu$ A/MHz, and 0.31  $\mu$ A for LVD) for the general-purpose and sensor control applications, with 2.7-V to 3.6-V operation, low pin counts (24 or 32 pins), small ROM capacity (16 Kbytes), and highly-functional analog circuits (12-bit A/D and 10-bit D/A converters)

## 1. OUTLINE

### 1.1 Features

- Minimum instruction execution time can be changed from high speed (0.03125  $\mu$ s: @ 32 MHz operation with high-speed on-chip oscillator) to low-speed (1  $\mu$ s: @ 1 MHz operation with high-speed on-chip oscillator)
- General-purpose registers: 8 bits  $\times$  32 registers (8 bits  $\times$  8 registers  $\times$  4 banks)
- ROM: 16 KB, RAM: 1.5 KB, Data flash: 2 KB
- High-speed on-chip oscillator
  - Select from 32 MHz (TYP.), 24 MHz (TYP.), 16 MHz (TYP.), 12 MHz (TYP.), 8 MHz (TYP.), 6 MHz (TYP.), 4 MHz (TYP.), 3 MHz (TYP.), 2 MHz (TYP.), and 1 MHz (TYP.)
- On-chip single-power supply flash memory (with prohibition of block erase/writing function)
- Self-programming
- On-chip debug function
- On-chip power-on-reset (POR) circuit and voltage detector (LVD)
- On-chip watchdog timer (operable with the dedicated low-speed on-chip oscillator)
- On-chip clock output/buzzer output controller
- On-chip BCD adjustment
- I/O ports: 26 or 28 (N-ch open drain: 2)
- Timer
  - 16-bit timer TAU: 4 channels
  - Watchdog timer: 1 channel
- Serial interface
  - CSI: 1 channel
  - UART: 1 channel
  - I<sup>2</sup>C: 1 channel (2 slave addresses)
- 8/12-bit resolution A/D converter ( $V_{DD}$  = 2.7 to 3.6 V): 6 or 8 channels
- Standby function: HALT, STOP, SNOOZE mode
- On-chip 10-bit D/A converter
- DMA controller: 2 channels
- On-chip event link controller (ELC)
- Power supply voltage:  $V_{DD}$  = 2.7 to 3.6 V
- Operating ambient temperature:  $T_A$  = -40 to +85°C (A: Consumer applications, D: Industrial applications)

**Remark** The functions mounted depend on the product. See **1.6 Outline of Functions**.

## O ROM, RAM capacities

| Flash ROM | Data Flash | RAM <sup>Note</sup> | 24-pin                   | 32-pin                   |
|-----------|------------|---------------------|--------------------------|--------------------------|
| 16 KB     | 2 KB       | 1.5 KB              | R5F11Z7AANA, R5F11Z7ADNA | R5F11ZBAAFP, R5F11ZBADFP |

**Note** The flash libraries use the on-chip RAM area from FFE20H to FFEFFH and the parts of the RAM area referred to as self RAM (RAM for use in self-programming), which are listed in the table below, for self-programming or rewriting of the data flash memory.

See below for the RAM areas used by the flash library.

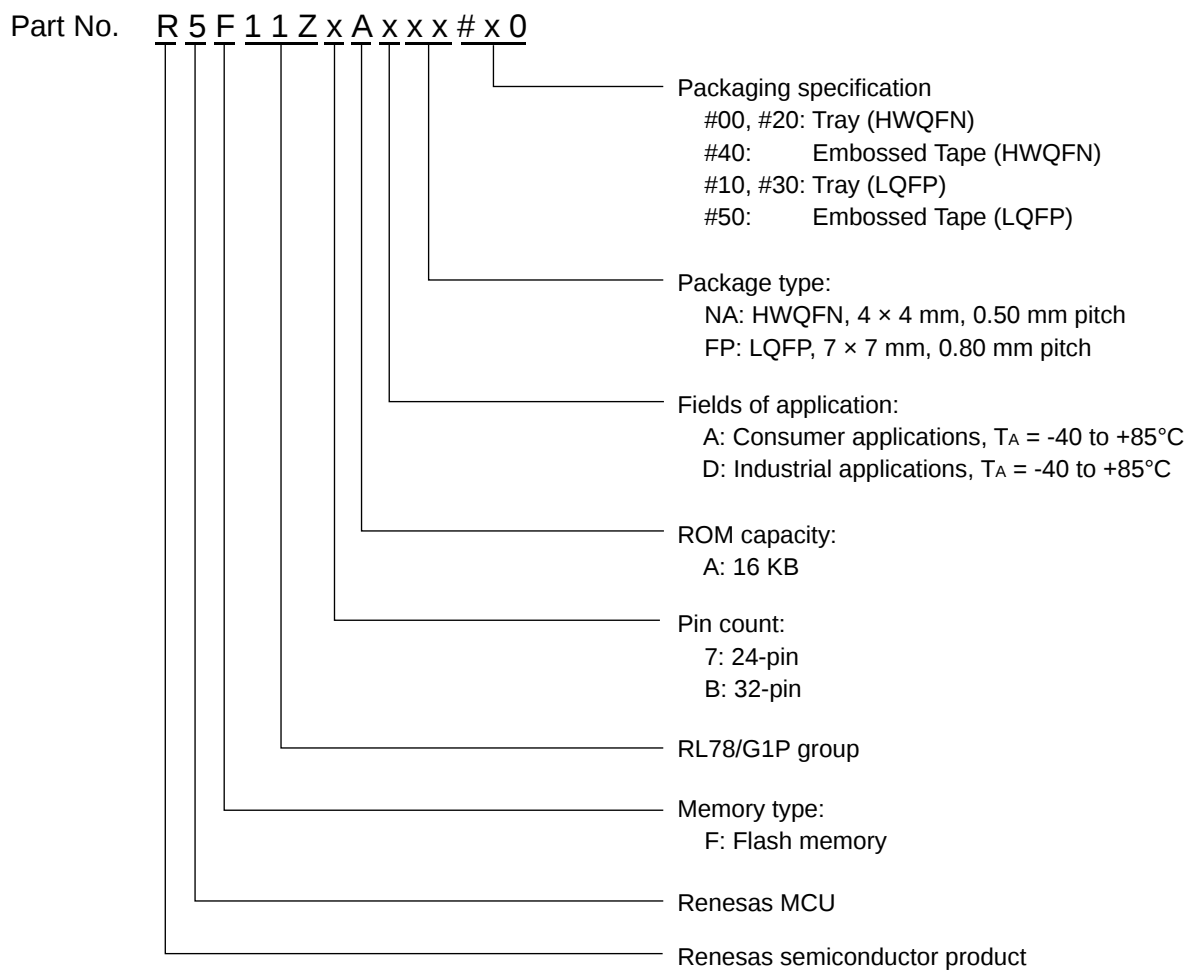
|                                                          | RAM    | FSL Type01                                 | FDL Type04                 | EEL Pack01, EEL Pack02 |
|----------------------------------------------------------|--------|--------------------------------------------|----------------------------|------------------------|
|                                                          |        | Self RAM size<br>896 bytes <sup>Note</sup> | Self RAM size<br>136 bytes |                        |
| R5F11Z7AANA<br>R5F11Z7ADNA<br>R5F11ZBAAFP<br>R5F11ZBADFP | 1.5 KB | FF900H to FFC7FH                           | FF900H to FF987H           | Not available          |

**Note** Functions supported in FSL Type01 are only basic functions. Other functions are not supported.

Basic functions: FSL\_Init, FSL\_Open, FSL\_Close, FSL\_PrepareFunctions, FSL\_BlankCheck, FSL\_Erase, FSL\_IVerify, FSL\_Write, and FSL\_StatusCheck

## 1.2 List of Part Numbers

Figure 1-1. Part Number, Memory Size, and Package

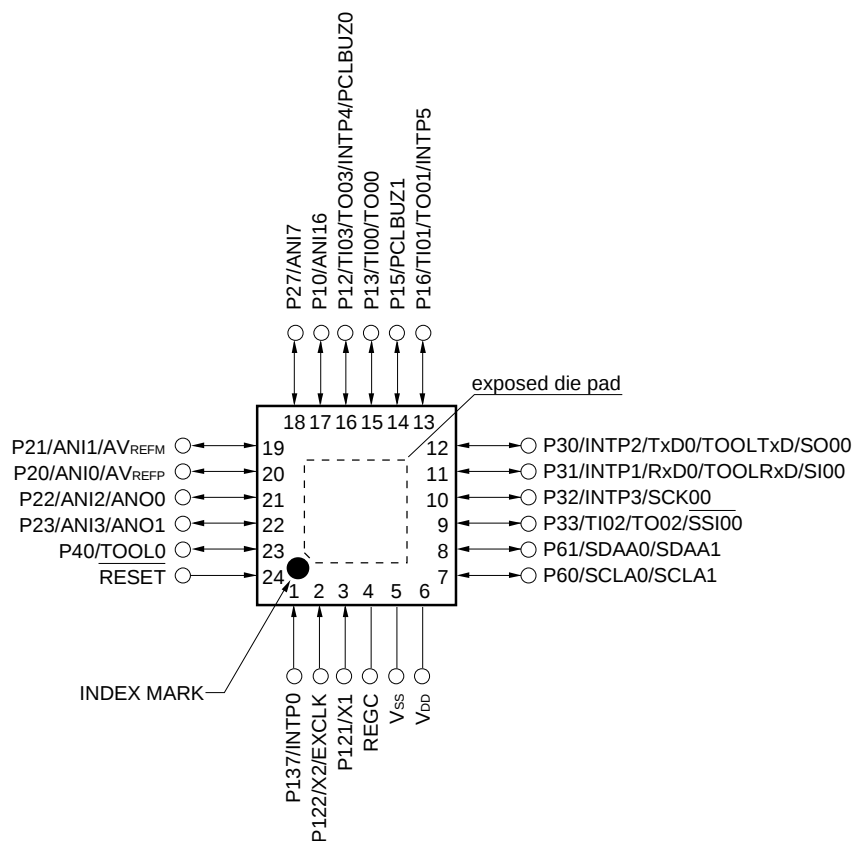


| Pin Count | Package                                          | Data Flash | Fields of Application | Packaging Specification | Part Number                       |
|-----------|--------------------------------------------------|------------|-----------------------|-------------------------|-----------------------------------|
| 24 pins   | 24-pin plastic HWQFN<br>(4 × 4 mm, 0.5 mm pitch) | 2 KB       | A                     | Tray                    | R5F11Z7AANA#00,<br>R5F11Z7AANA#20 |
|           |                                                  |            |                       | Embossed Tape           | R5F11Z7AANA#40                    |
|           |                                                  |            | D                     | Tray                    | R5F11Z7ADNA#00,<br>R5F11Z7ADNA#20 |
|           |                                                  |            |                       | Embossed Tape           | R5F11Z7ADNA#40                    |
| 32 pins   | 32-pin plastic LQFP<br>(7 × 7 mm, 0.8 mm pitch)  |            | A                     | Tray                    | R5F11ZBAAFP#10,<br>R5F11ZBAAFP#30 |
|           |                                                  |            |                       | Embossed Tape           | R5F11ZBAAFP#50                    |
|           |                                                  |            | D                     | Tray                    | R5F11ZBADFP#10,<br>R5F11ZBADFP#30 |
|           |                                                  |            |                       | Embossed Tape           | R5F11ZBADFP#50                    |

### 1.3 Pin Configuration (Top View)

#### 1.3.1 24-pin products

- 24-pin plastic HWQFN (4 × 4 mm, 0.5 mm pitch)



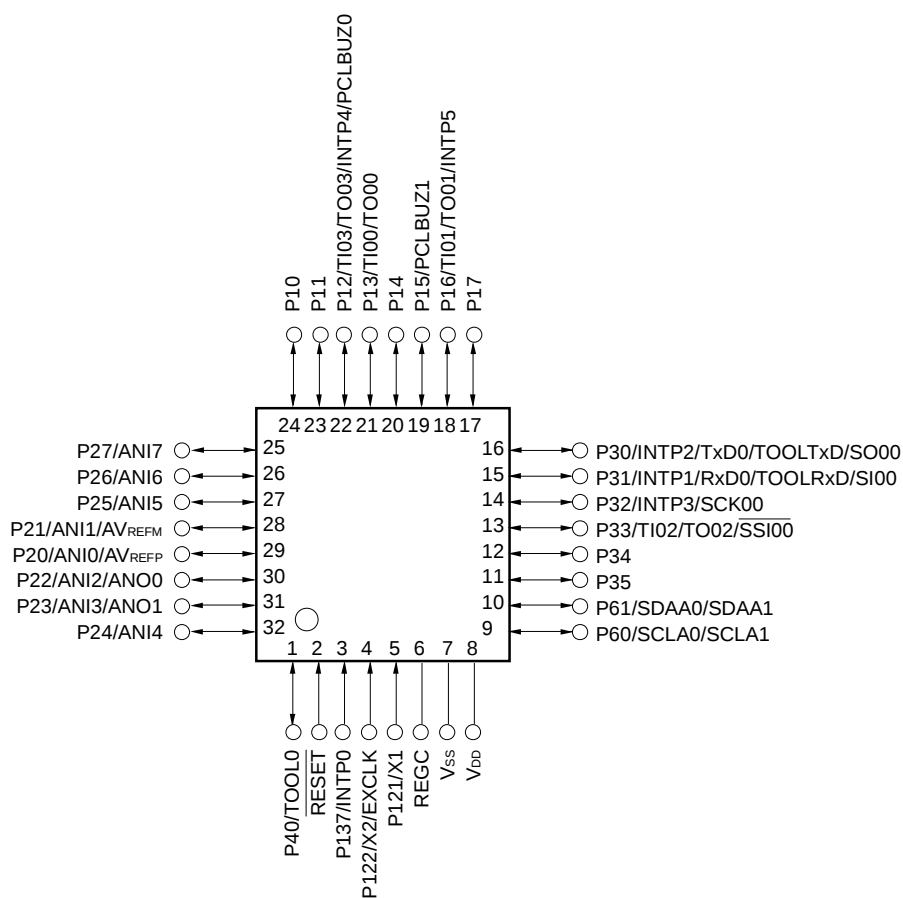
**Caution** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1  $\mu$ F).

**Remarks 1.** For pin identification, see **1.4 Pin Identification**.

**2.** It is recommended to connect an exposed die pad to V<sub>SS</sub>.

### 1.3.2 32-pin products

- 32-pin plastic LQFP (7 × 7 mm, 0.8 mm pitch)



**Caution** Connect the REGC pin to V<sub>SS</sub> via a capacitor (0.47 to 1  $\mu$ F).

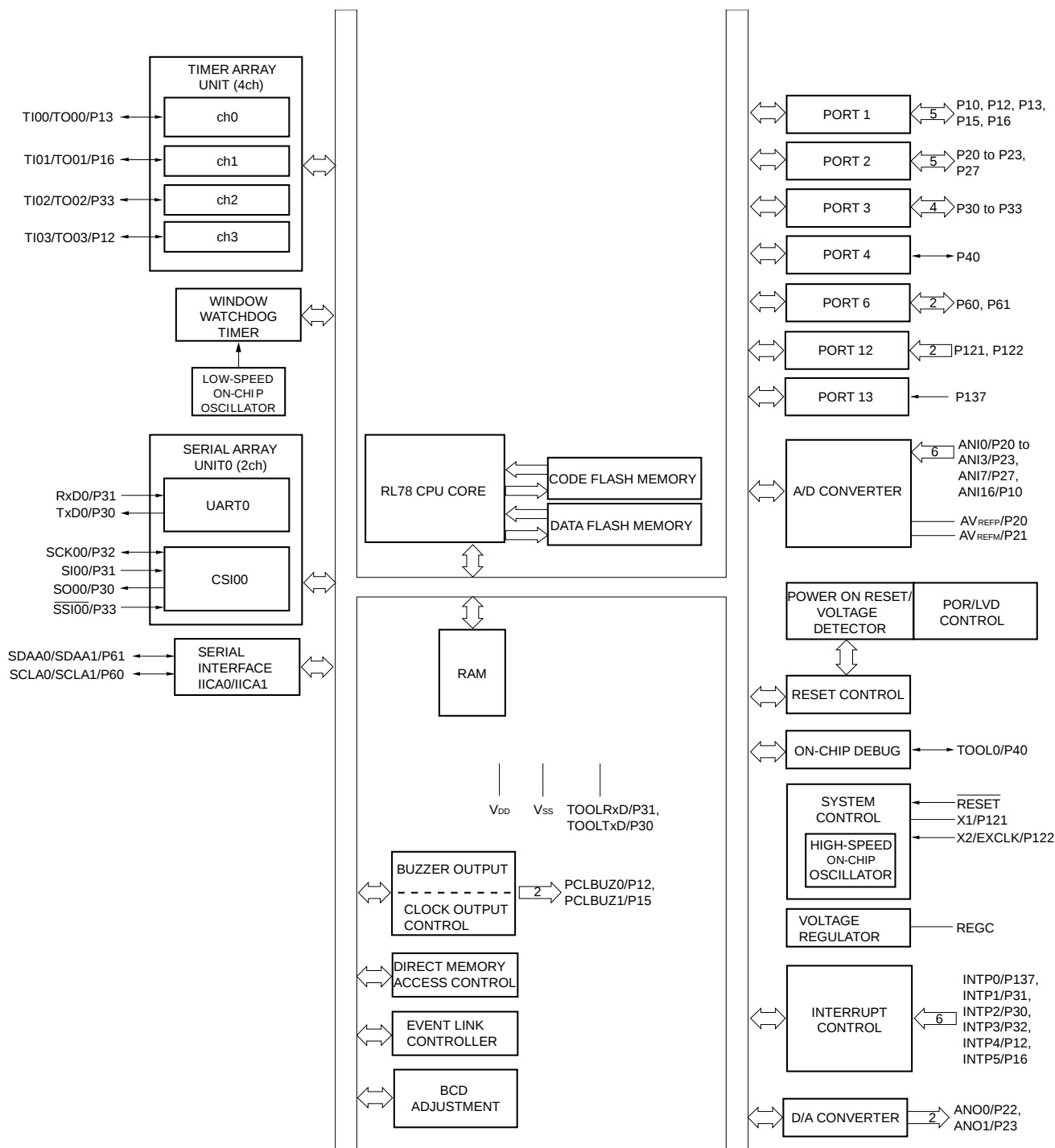
**Remark** For pin identification, see 1.4 Pin Identification.

## 1.4 Pin Identification

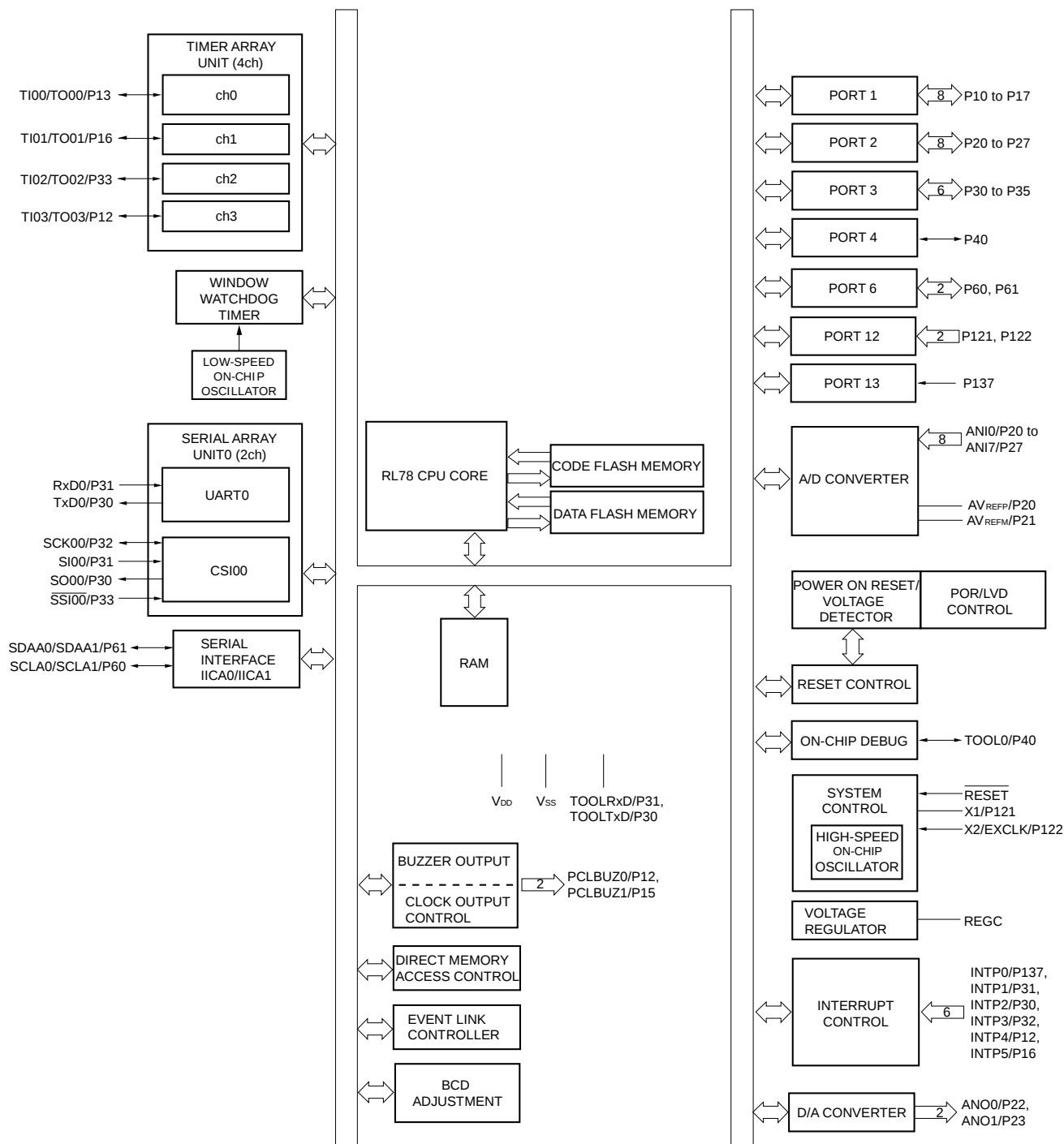
|                      |                                             |                      |                                        |
|----------------------|---------------------------------------------|----------------------|----------------------------------------|
| ANI0 to ANI7, ANI16: | Analog input                                | RxD0:                | Receive data                           |
| ANO0, ANO1:          | Analog output                               | SCK00:               | Serial clock input/output              |
| AVREFM:              | Analog reference voltage<br>minus           | SCLA0, SCLA1:        | Serial clock input/output              |
| AVREFP:              | Analog reference voltage<br>plus            | SDAA0, SDAA1:        | Serial data input/output               |
| EXCLK:               | External clock input<br>(main system clock) | SI00:                | Serial data input                      |
| INTP0 to INTP5:      | External Interrupt Input                    | SO00:                | Serial data output                     |
| P10 to P17:          | Port 1                                      | $\overline{SSI00}$ : | Serial interface chip select input     |
| P20 to P27:          | Port 2                                      | TI00 to TI03:        | Timer input                            |
| P30 to P35:          | Port 3                                      | TO00 to TO03:        | Timer output                           |
| P40:                 | Port 4                                      | TOOL0:               | Data input/output for tool             |
| P60, P61:            | Port 6                                      | TOOLRxD, TOOLTxD:    | Data input/output for external device  |
| P121, P122:          | Port 12                                     | TxD0:                | Transmit data                          |
| P137:                | Port 13                                     | V <sub>DD</sub> :    | Power supply                           |
| PCLBUZ0, PCLBUZ1:    | Programmable clock<br>output/buzzer output  | V <sub>SS</sub> :    | Ground                                 |
| REGC:                | Regulator capacitance                       | X1, X2:              | Crystal oscillator (main system clock) |
| $\overline{RESET}$ : | Reset                                       |                      |                                        |

## 1.5 Block Diagram

### 1.5.1 24-pin products



## 1.5.2 32-pin products



## 1.6 Outline of Functions

(1/2)

| Item                               |                                                        | 24-pin                                                                                                                                                                                                                                                                                   | 32-pin                        |
|------------------------------------|--------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------|
|                                    |                                                        | R5F11Z7AANA, R5F11Z7ADNA                                                                                                                                                                                                                                                                 | R5F11ZBAAFP, R5F11ZBADFP      |
| Code flash memory                  |                                                        | 16 KB                                                                                                                                                                                                                                                                                    |                               |
| Data flash memory                  |                                                        | 2 KB                                                                                                                                                                                                                                                                                     |                               |
| RAM                                |                                                        | 1.5 KB <sup>Note</sup>                                                                                                                                                                                                                                                                   |                               |
| Memory space                       |                                                        | 1 MB                                                                                                                                                                                                                                                                                     |                               |
| Main system clock                  | High-speed system clock                                | X1 (crystal/ceramic) oscillation, external main system clock input (EXCLK)<br>1 to 20 MHz: V <sub>DD</sub> = 2.7 to 3.6 V                                                                                                                                                                |                               |
|                                    | High-speed on-chip oscillator clock (f <sub>IH</sub> ) | High-speed operation: 32 MHz (V <sub>DD</sub> = 2.7 to 3.6 V)                                                                                                                                                                                                                            |                               |
| Low-speed on-chip oscillator clock |                                                        | 15 kHz (TYP.): V <sub>DD</sub> = 2.7 to 3.6 V                                                                                                                                                                                                                                            |                               |
| General-purpose registers          |                                                        | 8 bits × 32 registers (8 bits × 8 registers × 4 banks)                                                                                                                                                                                                                                   |                               |
| Minimum instruction execution time |                                                        | 0.03125 μs (High-speed on-chip oscillator: f <sub>IH</sub> = 32 MHz operation)                                                                                                                                                                                                           |                               |
|                                    |                                                        | 0.05 μs (High-speed system clock: f <sub>MX</sub> = 20 MHz operation)                                                                                                                                                                                                                    |                               |
| Instruction set                    |                                                        | <ul style="list-style-type: none"><li>• Data transfer (8/16 bits)</li><li>• Adder and subtractor/logical operation (8/16 bits)</li><li>• Multiplication (8 bits × 8 bits)</li><li>• Rotate, barrel shift, and bit manipulation (set, reset, test, and boolean operation), etc.</li></ul> |                               |
| I/O port                           | Total                                                  | 20                                                                                                                                                                                                                                                                                       | 28                            |
|                                    | CMOS I/O                                               | 15                                                                                                                                                                                                                                                                                       | 23                            |
|                                    | CMOS input                                             | 3                                                                                                                                                                                                                                                                                        | 3                             |
|                                    | N-ch O.D I/O (6 V tolerance)                           | 2                                                                                                                                                                                                                                                                                        | 2                             |
| Timer                              | 16-bit timer                                           | 4 channels (TAU)                                                                                                                                                                                                                                                                         |                               |
|                                    | Watchdog timer                                         | 1 channel                                                                                                                                                                                                                                                                                |                               |
|                                    | Timer output                                           | 4<br>PWM outputs: 3                                                                                                                                                                                                                                                                      |                               |
| Clock output/buzzer output         |                                                        | 2                                                                                                                                                                                                                                                                                        |                               |
|                                    |                                                        | <ul style="list-style-type: none"><li>• 2.44 kHz, 4.88 kHz, 9.77 kHz, 1.25 MHz, 2.5 MHz, 5 MHz, 10 MHz (Main system clock: f<sub>MAIN</sub> = 20 MHz operation)</li></ul>                                                                                                                |                               |
| 8/12-bit resolution A/D converter  |                                                        | 6 channels                                                                                                                                                                                                                                                                               | 8 channels                    |
| 10-bit D/A converter               |                                                        | 2 channels                                                                                                                                                                                                                                                                               |                               |
| Serial interface                   |                                                        | <ul style="list-style-type: none"><li>• CSI: 1 channel/UART: 1 channel</li></ul>                                                                                                                                                                                                         |                               |
|                                    |                                                        | I <sup>2</sup> C bus                                                                                                                                                                                                                                                                     | 1 channel (2 slave addresses) |
| DMA controller                     |                                                        | 2 channels                                                                                                                                                                                                                                                                               |                               |
| Event link controller (ELC)        |                                                        | Event input: 10, Event trigger output: 3                                                                                                                                                                                                                                                 |                               |
| Vectored interrupt sources         | Internal                                               | 12                                                                                                                                                                                                                                                                                       |                               |
|                                    | External                                               | 6                                                                                                                                                                                                                                                                                        |                               |

**Note** This is about 0.5 KB when the self-programming function and data flash function are used. For details, see **CHAPTER 3** in the RL78/G1P User's Manual.

(2/2)

| Item                          | 24-pin                                                                                                                                                                                                                                                                                                                                                                                                                 | 32-pin                   |
|-------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------|
|                               | R5F11Z7AANA, R5F11Z7ADNA                                                                                                                                                                                                                                                                                                                                                                                               | R5F11ZBAAFP, R5F11ZBADFP |
| Reset                         | <ul style="list-style-type: none"> <li>• Reset by <math>\overline{\text{RESET}}</math> pin</li> <li>• Internal reset by watchdog timer</li> <li>• Internal reset by power-on-reset</li> <li>• Internal reset by voltage detector</li> <li>• Internal reset by illegal instruction execution<sup>Note</sup></li> <li>• Internal reset by RAM parity error</li> <li>• Internal reset by illegal-memory access</li> </ul> |                          |
| Power-on-reset circuit        | <ul style="list-style-type: none"> <li>• Power-on-reset: 1.51 <math>\pm</math> 0.03 V</li> <li>• Power-down-reset: 1.50 <math>\pm</math> 0.03 V</li> </ul>                                                                                                                                                                                                                                                             |                          |
| Voltage detector              | 2.75 V to 3.13 V (4 stages)                                                                                                                                                                                                                                                                                                                                                                                            |                          |
| On-chip debug function        | Provided                                                                                                                                                                                                                                                                                                                                                                                                               |                          |
| Power supply voltage          | $V_{DD} = 2.7$ to $3.6$ V                                                                                                                                                                                                                                                                                                                                                                                              |                          |
| Operating ambient temperature | $T_A = -40$ to $+85^\circ\text{C}$                                                                                                                                                                                                                                                                                                                                                                                     |                          |

**Note** The illegal instruction is generated when instruction code FFH is executed.

Reset by the illegal instruction execution not issued by emulation with the in-circuit emulator or on-chip debug emulator.

## 2. ELECTRICAL SPECIFICATIONS

- Cautions**
1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.
  2. The pins mounted depend on the product. See 2.1 Pin Function List to 2.2.1 With functions for each product in the RL78/G1P User's Manual.

## 2.1 Absolute Maximum Ratings

### Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ ) (1/2)

| Parameter              | Symbols     | Conditions                                                          | Ratings                                                                         | Unit |
|------------------------|-------------|---------------------------------------------------------------------|---------------------------------------------------------------------------------|------|
| Supply voltage         | $V_{DD}$    |                                                                     | −0.5 to +4.6                                                                    | V    |
|                        | $V_{SS}$    |                                                                     | −0.5 to +0.3                                                                    | V    |
| REGC pin input voltage | $V_{IREGC}$ | REGC                                                                | −0.3 to +2.8<br>and −0.3 to $V_{DD} + 0.3$ <sup>Note 1</sup>                    | V    |
| Input voltage          | $V_{I1}$    | P10 to P17, P20 to P27, P30 to P35, P40, P121, P122, P137           | −0.3 to $V_{DD} + 0.3$ <sup>Note 2</sup>                                        | V    |
|                        | $V_{I2}$    | P60, P61 (N-ch open-drain)                                          | −0.3 to +6.5                                                                    | V    |
| Output voltage         | $V_{O1}$    | P10 to P17, P20 to P27, P30 to P35, P40, P60, P61, P121, P122, P137 | −0.3 to $V_{DD} + 0.3$ <sup>Note 2</sup>                                        | V    |
| Analog input voltage   | $V_{AI1}$   | ANI0 to ANI7, ANI16                                                 | −0.3 to $V_{DD} + 0.3$<br>and −0.3 to $AV_{REF(+)} + 0.3$ <sup>Notes 2, 3</sup> | V    |

**Notes 1.** Connect the REGC pin to  $V_{SS}$  via a capacitor (0.47 to 1  $\mu\text{F}$ ). This value regulates the absolute maximum rating of the REGC pin. Do not use this pin with voltage applied to it.

**2.** Must be 4.6 V or lower.

**3.** Do not exceed  $AV_{REF(+)} + 0.3$  V in case of A/D conversion target pin.

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remarks 1.** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

**2.**  $AV_{REF(+)}$ : + side reference voltage of the A/D converter.

**3.**  $V_{SS}$ : Reference voltage

**Absolute Maximum Ratings (T<sub>A</sub> = 25°C) (2/2)**

| Parameter                     | Symbols          | Conditions                       |                                       | Ratings     | Unit |
|-------------------------------|------------------|----------------------------------|---------------------------------------|-------------|------|
| Output current, high          | I <sub>OH1</sub> | Per pin                          | P10 to P17, P30 to P35, P40           | −40         | mA   |
|                               |                  | Total of all pins<br>−140 mA     | P40                                   | −40         | mA   |
|                               |                  |                                  | P10 to P17, P30, P35                  | −100        | mA   |
|                               | I <sub>OH2</sub> | Per pin                          | P20 to P27                            | −0.5        | mA   |
|                               |                  | Total of all pins                |                                       | −2          | mA   |
| Output current, low           | I <sub>OL1</sub> | Per pin                          | P10 to P17, P30 to P35, P40, P60, P61 | 40          | mA   |
|                               |                  | Total of all pins<br>140 mA      | P40                                   | 40          | mA   |
|                               |                  |                                  | P10 to P17, P30 to P35, P60, P61      | 100         | mA   |
|                               | I <sub>OL2</sub> | Per pin                          | P20 to P27                            | 1           | mA   |
|                               |                  | Total of all pins                |                                       | 5           | mA   |
| Operating ambient temperature | T <sub>A</sub>   | In normal operation mode         |                                       | −40 to +85  | °C   |
|                               |                  | In flash memory programming mode |                                       | 0 to +40    |      |
| Storage temperature           | T <sub>stg</sub> |                                  |                                       | −65 to +150 | °C   |

**Caution** Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 2.2 Oscillator Characteristics

### 2.2.1 X1 oscillator characteristics

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

| Parameter                                                | Resonator                               | Conditions                                   | MIN. | TYP. | MAX. | Unit |
|----------------------------------------------------------|-----------------------------------------|----------------------------------------------|------|------|------|------|
| X1 clock oscillation frequency ( $f_x$ ) <sup>Note</sup> | Ceramic resonator/<br>crystal resonator | $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | 1.0  |      | 20.0 | MHz  |

**Note** Indicates only oscillator characteristics. See **2.4 AC Characteristics** for instruction execution time.  
Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

**Caution** Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

**Remark** When using the X1 oscillator, refer to **5.4 System Clock Oscillator** in the RL78/G1P User's Manual.

### 2.2.2 On-chip oscillator characteristics

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

| Oscillators                                                         | Parameters | Conditions                 |                                              | MIN. | TYP. | MAX. | Unit |
|---------------------------------------------------------------------|------------|----------------------------|----------------------------------------------|------|------|------|------|
| High-speed on-chip oscillator clock frequency <sup>Notes 1, 2</sup> | $f_{IH}$   | 32 MHz selected            |                                              | 1    |      | 32   | MHz  |
|                                                                     |            | 24 MHz selected            |                                              | 1    |      | 24   | MHz  |
| High-speed on-chip oscillator clock frequency accuracy              |            | -20 to $+85^\circ\text{C}$ | $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | -1.0 |      | +1.0 | %    |
|                                                                     |            | -40 to $-20^\circ\text{C}$ | $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ | -1.5 |      | +1.5 | %    |
| Low-speed on-chip oscillator clock frequency <sup>Note 2</sup>      | $f_{IL}$   |                            |                                              |      | 15   |      | kHz  |
| Low-speed on-chip oscillator clock frequency accuracy               |            |                            |                                              | -15  |      | +15  | %    |

**Notes 1.** High-speed on-chip oscillator frequency is selected by bits 0 to 3 of option byte (000C2H) and bits 0 to 2 of HOCODIV register.

**2.** This indicates the oscillator characteristics only. See **2.4 AC Characteristics** for instruction execution time.

## 2.3 DC Characteristics

### 2.3.1 Pin characteristics

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ ) (1/3)

| Items                                  | Symbol           | Conditions                                                                    | MIN. | TYP. | MAX.                   | Unit |
|----------------------------------------|------------------|-------------------------------------------------------------------------------|------|------|------------------------|------|
| Output current, high <sup>Note 1</sup> | I <sub>OH1</sub> | Per pin for P10 to P17, P30 to P35, P40                                       |      |      | -2.0 <sup>Note 2</sup> | mA   |
|                                        |                  | Total of P10 to P17, P30 to P35<br>(When duty $\leq 70\%$ <sup>Note 3</sup> ) |      |      | -19.0                  | mA   |
|                                        |                  | Total of all pins<br>(When duty $\leq 70\%$ <sup>Note 3</sup> )               |      |      | -21.0                  | mA   |
|                                        | I <sub>OH2</sub> | Per pin for P20 to P27                                                        |      |      | -0.1                   | mA   |
|                                        |                  | Total of all pins<br>(When duty $\leq 70\%$ <sup>Note 3</sup> )               |      |      | -0.8                   | mA   |

- Notes**
1. Value of current at which the device operation is guaranteed even if the current flows from the  $V_{DD}$  pin to an output pin.
  2. Do not exceed the total current value.
  3. Specification under conditions where the duty factor  $\leq 70\%$ .

The output current value that has changed to the duty factor  $> 70\%$  the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins =  $(I_{OH} \times 0.7)/(n \times 0.01)$

<Example> Where  $n = 80\%$  and  $I_{OH} = -19.0\text{ mA}$

$$\text{Total output current of pins} = (-19.0 \times 0.7)/(80 \times 0.01) = -16.625\text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V) (2/3)

| Items                                 | Symbol           | Conditions                                                                        | MIN. | TYP. | MAX.                  | Unit |
|---------------------------------------|------------------|-----------------------------------------------------------------------------------|------|------|-----------------------|------|
| Output current, low <sup>Note 1</sup> | I <sub>OL1</sub> | Per pin for P10 to P17, P30 to P35, P40                                           |      |      | 3.0 <sup>Note 2</sup> | mA   |
|                                       |                  | Per pin for P60, P61                                                              |      |      | 3.0 <sup>Note 2</sup> | mA   |
|                                       |                  | Total of P10 to P17, P30 to P35, P60, P61<br>(When duty ≤ 70% <sup>Note 3</sup> ) |      |      | 35.0                  | mA   |
|                                       |                  | Total of all pins<br>(When duty ≤ 70% <sup>Note 3</sup> )                         |      |      | 38.0                  | mA   |
|                                       | I <sub>OL2</sub> | Per pin for P20 to P27                                                            |      |      | 0.4                   | mA   |
|                                       |                  | Total of all pins<br>(When duty ≤ 70% <sup>Note 3</sup> )                         |      |      | 3.2                   | mA   |

**Notes** 1. Value of current at which the device operation is guaranteed even if the current flows from an output pin to the V<sub>SS</sub> pin.

2. However, do not exceed the total current value.

3. Specification under conditions where the duty factor ≤ 70%.

The output current value that has changed to the duty factor > 70% the duty ratio can be calculated with the following expression (when changing the duty factor from 70% to n%).

- Total output current of pins = (I<sub>OL</sub> × 0.7)/(n × 0.01)

<Example> Where n = 80% and I<sub>OL</sub> = 35.0 mA

$$\text{Total output current of pins} = (35.0 \times 0.7) / (80 \times 0.01) = 30.625 \text{ mA}$$

However, the current that is allowed to flow into one pin does not vary depending on the duty factor. A current higher than the absolute maximum rating must not flow into one pin.

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V) (3/3)

| Items                       | Symbol            | Conditions                                                  |                                                  | MIN.                                  | TYP. | MAX.               | Unit |    |
|-----------------------------|-------------------|-------------------------------------------------------------|--------------------------------------------------|---------------------------------------|------|--------------------|------|----|
| Input voltage, high         | V <sub>IH1</sub>  | P10 to P17, P30 to P35, P40, P121, P122, P137, EXCLK, RESET |                                                  | 0.8V <sub>DD</sub>                    |      | V <sub>DD</sub>    | V    |    |
|                             | V <sub>IH2</sub>  | P20 to P27                                                  |                                                  | 0.7V <sub>DD</sub>                    |      | V <sub>DD</sub>    | V    |    |
|                             | V <sub>IH3</sub>  | P60, P61                                                    |                                                  | 0.7V <sub>DD</sub>                    |      | 6.0                | V    |    |
| Input voltage, low          | V <sub>IL1</sub>  | P10 to P17, P30 to P35, P40, P121, P122, P137, EXCLK, RESET |                                                  | 0                                     |      | 0.2V <sub>DD</sub> | V    |    |
|                             | V <sub>IL2</sub>  | P20 to P27, P60, P61                                        |                                                  | 0                                     |      | 0.3V <sub>DD</sub> | V    |    |
| Output voltage, high        | V <sub>OH1</sub>  | P10 to P17, P30 to P35, P40                                 | I <sub>OH1</sub> = −2.0 mA                       | V <sub>DD</sub> − 0.6                 |      |                    | V    |    |
|                             | V <sub>OH2</sub>  | P20 to P27                                                  | I <sub>OH1</sub> = −100 μA                       | V <sub>DD</sub> − 0.5                 |      |                    | V    |    |
| Output voltage, low         | V <sub>OL1</sub>  | P10 to P17, P30 to P35, P40                                 | I <sub>OL1</sub> = 3.0 mA                        |                                       |      | 0.6                | V    |    |
|                             |                   |                                                             | I <sub>OL1</sub> = 1.5 mA                        |                                       |      | 0.4                | V    |    |
|                             | V <sub>OL2</sub>  | P20 to P27                                                  | I <sub>OL2</sub> = 400 μA                        |                                       |      | 0.4                | V    |    |
|                             | V <sub>OL3</sub>  | P60, P61                                                    | I <sub>OL3</sub> = 3.0 mA                        |                                       |      | 0.4                | V    |    |
| Input leakage current, high | I <sub>LIH1</sub> | P10 to P17, P20 to P27, P30 to P35, P40, P137, RESET        | V <sub>I</sub> = V <sub>DD</sub>                 |                                       |      | 1                  | μA   |    |
|                             | I <sub>LIH2</sub> | P121, P122 (X1, X2, EXCLK)                                  | V <sub>I</sub> = V <sub>DD</sub>                 | In input port or external clock input |      | 1                  | μA   |    |
|                             |                   |                                                             |                                                  | In resonator connection               |      | 10                 | μA   |    |
| Input leakage current, low  | I <sub>LIL1</sub> | P10 to P17, P20 to P27, P30 to P35, P40, P137, RESET        | V <sub>I</sub> = V <sub>SS</sub>                 |                                       |      | −1                 | μA   |    |
|                             | I <sub>LIL2</sub> | P121, P122 (X1, X2, EXCLK)                                  | V <sub>I</sub> = V <sub>SS</sub>                 | In input port or external clock input |      | −1                 | μA   |    |
|                             |                   |                                                             |                                                  | In resonator connection               |      | −10                | μA   |    |
| On-chip pull-up resistance  | R <sub>U</sub>    | P10 to P17, P30 to P35, P40                                 | V <sub>I</sub> = V <sub>SS</sub> , In input port |                                       | 10   | 20                 | 100  | kΩ |

**Remark** Unless specified otherwise, the characteristics of alternate-function pins are the same as those of the port pins.

## 2.3.2 Supply current characteristics

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V) (1/3)

| Parameter      | Symbol                             | Conditions     |                                             |                                                                         |                  |                         | MIN. | TYP. | MAX. | Unit |
|----------------|------------------------------------|----------------|---------------------------------------------|-------------------------------------------------------------------------|------------------|-------------------------|------|------|------|------|
| Supply current | I <sub>DD1</sub> <sup>Note 1</sup> | Operating mode | HS (high-speed main) mode <sup>Note 4</sup> | f <sub>IH</sub> = 32 MHz <sup>Note 3</sup>                              | Basic operation  | V <sub>DD</sub> = 3.0 V |      | 2.1  |      | mA   |
|                |                                    |                |                                             |                                                                         | Normal operation | V <sub>DD</sub> = 3.0 V |      | 4.8  | 7.0  | mA   |
|                |                                    |                |                                             | f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>                              | Normal operation | V <sub>DD</sub> = 3.0 V |      | 3.8  | 5.5  | mA   |
|                |                                    |                |                                             | f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>                              | Normal operation | V <sub>DD</sub> = 3.0 V |      | 2.8  | 4.0  | mA   |
|                |                                    |                | LS (low-speed main) mode <sup>Note 4</sup>  | f <sub>IH</sub> = 8 MHz <sup>Note 3</sup>                               | Normal operation | V <sub>DD</sub> = 3.0 V |      | 1.3  | 2.0  | mA   |
|                |                                    |                | HS (high-speed main) mode <sup>Note 4</sup> | f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> ,<br>V <sub>DD</sub> = 3.0 V | Normal operation | Square wave input       |      | 3.3  | 4.6  | mA   |
|                |                                    |                |                                             |                                                                         |                  | Resonator connection    |      | 3.5  | 4.8  |      |
|                |                                    |                |                                             | f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> ,<br>V <sub>DD</sub> = 3.0 V | Normal operation | Square wave input       |      | 2.0  | 2.7  | mA   |
|                |                                    |                |                                             |                                                                         |                  | Resonator connection    |      | 2.1  | 2.7  |      |
|                |                                    |                | LS (low-speed main) mode <sup>Note 4</sup>  | f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> ,<br>V <sub>DD</sub> = 3.0 V  | Normal operation | Square wave input       |      | 1.2  | 2.0  | mA   |
|                |                                    |                |                                             |                                                                         |                  | Resonator connection    |      | 1.2  | 2.0  |      |

**Notes 1.** Total current flowing into V<sub>DD</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub> or V<sub>SS</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

**2.** When high-speed on-chip oscillator is stopped.

**3.** When high-speed system clock is stopped.

**4.** Relationship between operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode: @1 MHz to 32 MHz

LS (low-speed main) mode: @1 MHz to 8 MHz

**Remarks 1.** f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

**2.** f<sub>IH</sub>: High-speed on-chip oscillator clock frequency

**3.** Temperature condition of the TYP. value is T<sub>A</sub> = 25°C

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V) (2/3)

| Parameter                        | Symbol                             | Conditions |                                             |                                                                         |                         | MIN. | TYP. | MAX. | Unit |    |
|----------------------------------|------------------------------------|------------|---------------------------------------------|-------------------------------------------------------------------------|-------------------------|------|------|------|------|----|
| Supply current <sup>Note 1</sup> | I <sub>DD2</sub> <sup>Note 2</sup> | HALT mode  | HS (high-speed main) mode <sup>Note 6</sup> | f <sub>IH</sub> = 32 MHz <sup>Note 4</sup>                              | V <sub>DD</sub> = 3.0 V |      | 0.60 | 1.63 | mA   |    |
|                                  |                                    |            |                                             | f <sub>IH</sub> = 24 MHz <sup>Note 4</sup>                              | V <sub>DD</sub> = 3.0 V |      | 0.49 | 1.28 | mA   |    |
|                                  |                                    |            |                                             | f <sub>IH</sub> = 16 MHz <sup>Note 4</sup>                              | V <sub>DD</sub> = 3.0 V |      | 0.45 | 1.00 | mA   |    |
|                                  |                                    |            | LS (low-speed main) mode <sup>Note 6</sup>  | f <sub>IH</sub> = 8 MHz <sup>Note 4</sup>                               | V <sub>DD</sub> = 3.0 V |      | 320  | 530  | μA   |    |
|                                  |                                    |            | HS (high-speed main) mode <sup>Note 6</sup> | f <sub>MX</sub> = 20 MHz <sup>Note 3</sup> ,<br>V <sub>DD</sub> = 3.0 V | Square wave input       |      | 0.28 | 1.00 | mA   |    |
|                                  |                                    |            |                                             |                                                                         | Resonator connection    |      | 0.49 | 1.17 | mA   |    |
|                                  |                                    |            |                                             | f <sub>MX</sub> = 10 MHz <sup>Note 3</sup> ,<br>V <sub>DD</sub> = 3.0 V | Square wave input       |      | 0.19 | 0.60 | mA   |    |
|                                  |                                    |            |                                             |                                                                         | Resonator connection    |      | 0.30 | 0.67 | mA   |    |
|                                  |                                    |            | LS (low-speed main) mode <sup>Note 6</sup>  | f <sub>MX</sub> = 8 MHz <sup>Note 3</sup> ,<br>V <sub>DD</sub> = 3.0 V  | Square wave input       |      | 95   | 330  | μA   |    |
|                                  |                                    |            |                                             |                                                                         | Resonator connection    |      | 145  | 380  |      |    |
|                                  | I <sub>DD3</sub> <sup>Note 5</sup> | STOP mode  | T <sub>A</sub> = −40°C                      |                                                                         |                         |      |      | 0.18 |      | μA |
|                                  |                                    |            | T <sub>A</sub> = +25°C                      |                                                                         |                         |      |      | 0.23 | 0.50 |    |
|                                  |                                    |            | T <sub>A</sub> = +50°C                      |                                                                         |                         |      |      | 0.26 | 1.10 |    |
|                                  |                                    |            | T <sub>A</sub> = +70°C                      |                                                                         |                         |      |      | 0.29 | 1.90 |    |
|                                  |                                    |            | T <sub>A</sub> = +85°C                      |                                                                         |                         |      |      | 0.90 | 3.30 |    |

**Notes** 1. Total current flowing into V<sub>DD</sub>, including the input leakage current flowing when the level of the input pin is fixed to V<sub>DD</sub> or V<sub>SS</sub>. The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, D/A converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

2. During HALT instruction execution by flash memory.

3. When high-speed on-chip oscillator is stopped.

4. When high-speed system clock is stopped.

5. When high-speed on-chip oscillator and high-speed system clock are stopped. When watchdog timer is stopped. The values below the MAX. column include the leakage current.

6. Relationship between operation frequency of CPU and operation mode is as below.

HS (high-speed main) mode: @1 MHz to 32 MHz

LS (low-speed main) mode: @1 MHz to 8 MHz

**Remarks** 1. f<sub>MX</sub>: High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

2. f<sub>IH</sub>: High-speed on-chip oscillator clock frequency

3. Except STOP mode, temperature condition of the TYP. value is T<sub>A</sub> = 25°C

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V) (3/3)

| Parameter                               | Symbol                                    | Conditions                                                | MIN. | TYP. | MAX.  | Unit |
|-----------------------------------------|-------------------------------------------|-----------------------------------------------------------|------|------|-------|------|
| Watchdog timer operating current        | I <sub>WDT</sub> <sup>Notes 1, 2, 3</sup> | f <sub>IL</sub> = 15 kHz                                  |      | 0.22 |       | μA   |
| A/D converter operating current         | I <sub>ADC</sub> <sup>Notes 1, 4</sup>    | V <sub>DD</sub> = 3.0 V, When conversion at maximum speed |      | 0.58 | 0.82  | mA   |
| A/D converter reference voltage current | I <sub>ADREF</sub> <sup>Note 1</sup>      |                                                           |      | 75.0 |       | μA   |
| Temperature sensor operating current    | I <sub>TMPS</sub> <sup>Note 1</sup>       |                                                           |      | 75.0 |       | μA   |
| D/A converter operating current         | I <sub>DAC</sub> <sup>Notes 1, 5</sup>    |                                                           |      |      | 2     | mA   |
| LVD operating current                   | I <sub>LVI</sub> <sup>Notes 1, 6</sup>    |                                                           |      | 0.08 |       | μA   |
| Self-programming operating current      | I <sub>FSP</sub> <sup>Notes 1, 8</sup>    |                                                           |      | 2.50 | 12.20 | mA   |
| BGO operating current                   | I <sub>BGO</sub> <sup>Notes 1, 7</sup>    |                                                           |      | 2.50 | 12.20 | mA   |

**Notes 1.** Current flowing to V<sub>DD</sub>.

2. When high speed on-chip oscillator and high-speed system clock are stopped.
3. Current flowing only to the watchdog timer (including the operating current of the 15 kHz low-speed on-chip oscillator). The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub>, I<sub>DD2</sub> or I<sub>DD3</sub> and I<sub>WDT</sub> when the watchdog timer is in operation.
4. Current flowing only to the A/D converter. The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub> or I<sub>DD2</sub> and I<sub>ADC</sub> when the A/D converter operates in an operation mode or the HALT mode.
5. Current flowing only to the D/A converter. The supply current of the RL78 microcontrollers is the sum of I<sub>DD1</sub> or I<sub>DD2</sub> and I<sub>DAC</sub> when the D/A converter operates in an operation mode or the HALT mode.
6. Current flowing only to the LVD circuit. The supply current value of the RL78 microcontrollers is the sum of I<sub>DD1</sub>, I<sub>DD2</sub> or I<sub>DD3</sub> and I<sub>LVD</sub> when the LVD circuit is in operation.
7. Current flowing during programming of the data flash.
8. Current flowing during self-programming.

**Remarks 1.** f<sub>IL</sub>: Low-speed on-chip oscillator clock frequency2. f<sub>CLK</sub>: CPU/peripheral hardware clock frequency3. Temperature condition of the TYP. value is T<sub>A</sub> = 25°C

## 2.4 AC Characteristics

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

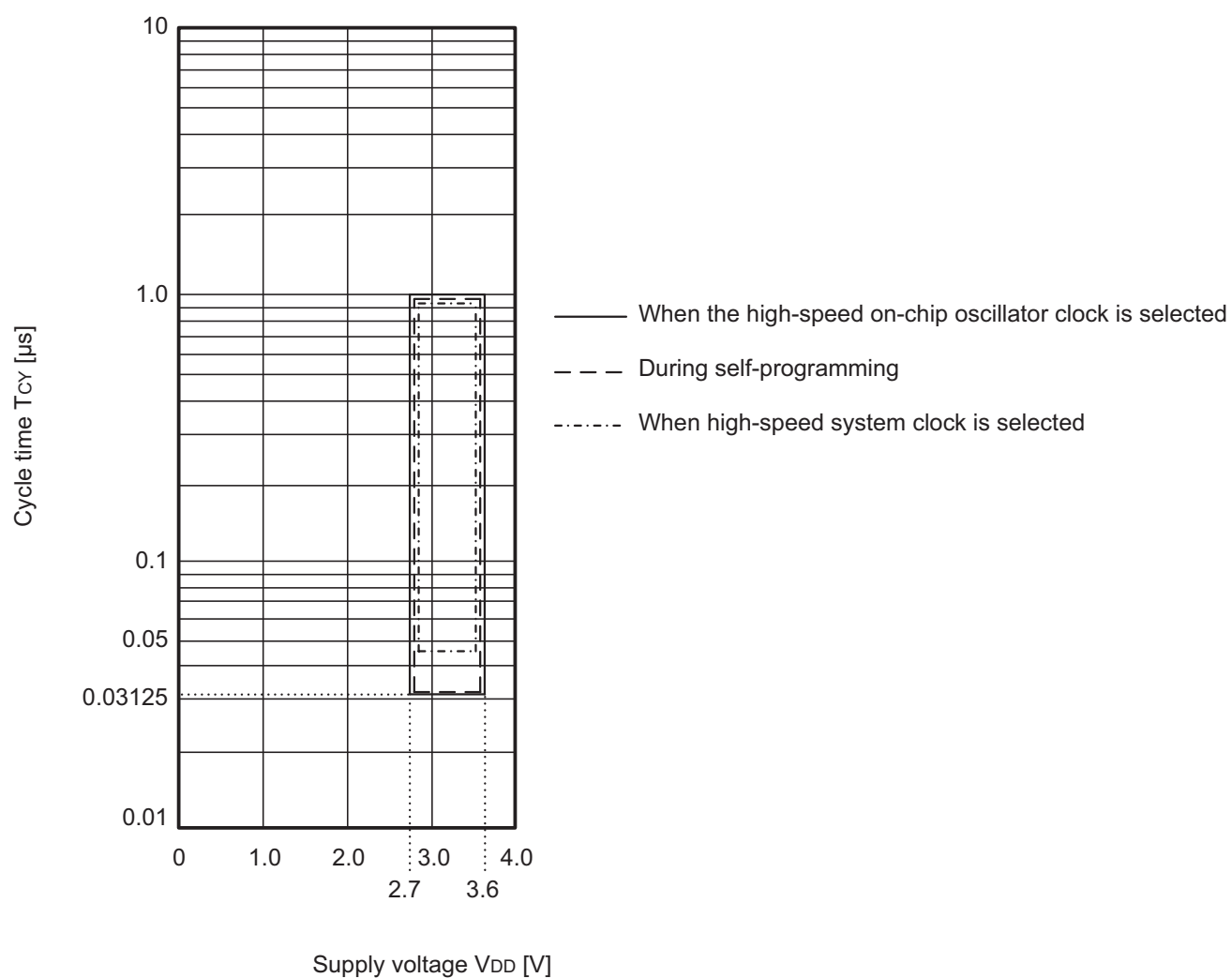
| Items                                                         | Symbol                     | Conditions                                 | MIN.           | TYP. | MAX. | Unit          |
|---------------------------------------------------------------|----------------------------|--------------------------------------------|----------------|------|------|---------------|
| Instruction cycle (minimum instruction execution time)        | $T_{CY}$                   | Main system clock ( $f_{MAIN}$ ) operation |                |      |      |               |
|                                                               |                            | HS (high-speed main) mode                  | 0.03125        |      | 1    | $\mu\text{s}$ |
|                                                               |                            | LS (low-speed main) mode                   | 0.125          |      | 1    | $\mu\text{s}$ |
|                                                               |                            | In the self-programming mode               |                |      |      |               |
|                                                               |                            | HS (high-speed main) mode                  | 0.03125        |      | 1    | $\mu\text{s}$ |
|                                                               |                            | LS (low-speed main) mode                   | 0.125          |      | 1    | $\mu\text{s}$ |
| External system clock frequency                               | $f_{EX}$                   |                                            | 1.0            |      | 20.0 | MHz           |
| External system clock input high-level width, low-level width | $t_{EXH}$ ,<br>$t_{EXL}$   |                                            | 24             |      |      | ns            |
| TI00 to TI03 input high-level width, low-level width          | $t_{TIH}$ ,<br>$t_{TIL}$   |                                            | $1/f_{MCK}+10$ |      |      | ns            |
| TO00 to TO03 output frequency                                 | $f_{TO}$                   | HS (high-speed main) mode                  |                |      | 8    | MHz           |
|                                                               |                            | LS (low-speed main) mode                   |                |      | 4    | MHz           |
| PCLBUZ0, PCLBUZ1 output frequency                             | $f_{PCL}$                  | HS (high-speed main) mode                  |                |      | 8    | MHz           |
|                                                               |                            | LS (low-speed main) mode                   |                |      | 4    | MHz           |
| Interrupt input high-level width, low-level width             | $t_{INTH}$ ,<br>$t_{INTL}$ | INTP0 to INTP5                             | 1              |      |      | $\mu\text{s}$ |
| RESET low-level width                                         | $t_{RSL}$                  |                                            | 10             |      |      | $\mu\text{s}$ |

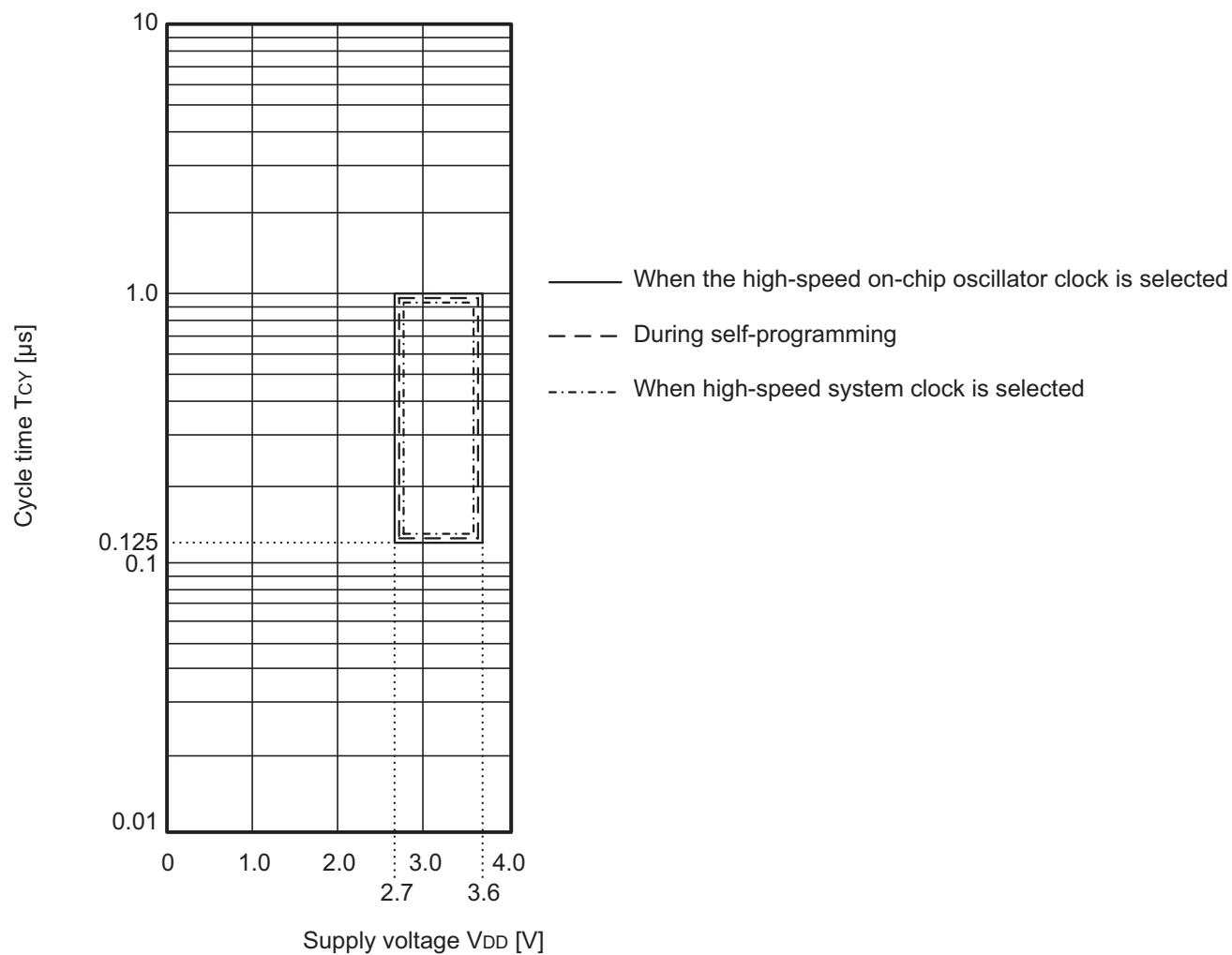
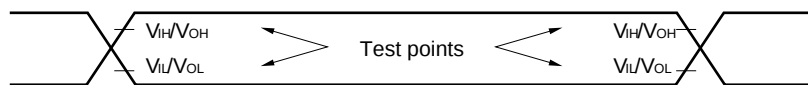
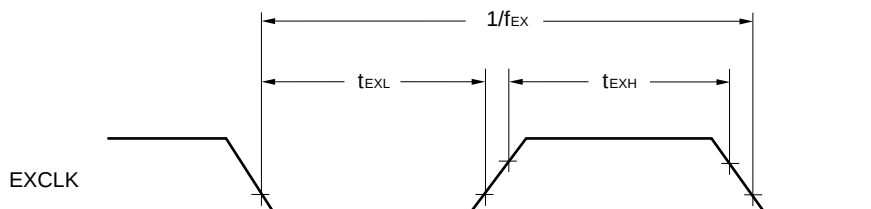
**Remark**  $f_{MCK}$ : Timer array unit operation clock frequency

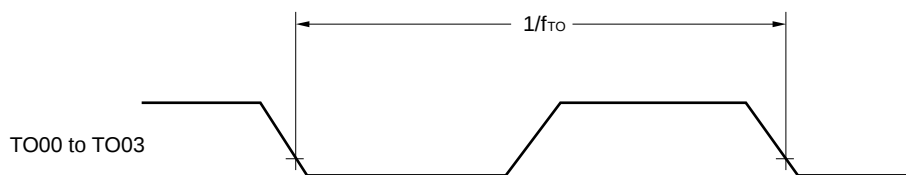
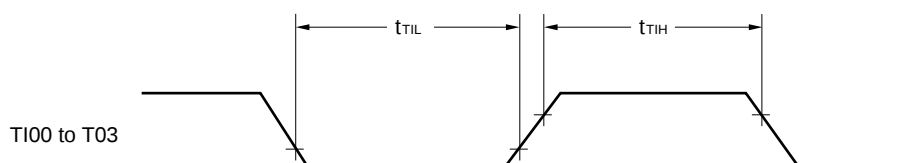
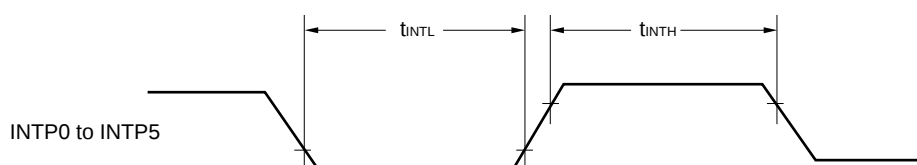
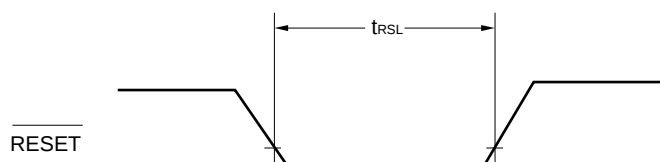
(Operation clock to be set by the CKSmn0 and CKSmn1 bits of timer mode register mn (TMRmn).

m: Unit number (m = 0), n: Channel number (n = 0 to 3))

## Minimum Instruction Execution Time during Main System Clock Operation

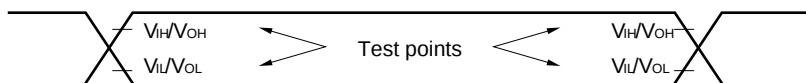
TCY vs V<sub>DD</sub> (HS (high-speed main) mode)

TCY vs  $V_{DD}$  (LS (low-speed main) mode)**AC Timing Test Points****External System Clock Timing**

**TI/TO Timing****Interrupt Request Input Timing****RESET Input Timing**

## 2.5 Peripheral Functions Characteristics

### AC Timing Test Points



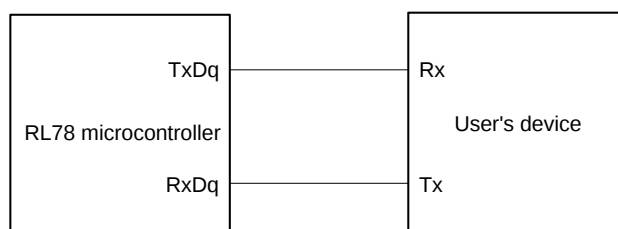
#### 2.5.1 Serial array unit

##### (1) During communication at same potential (UART mode)

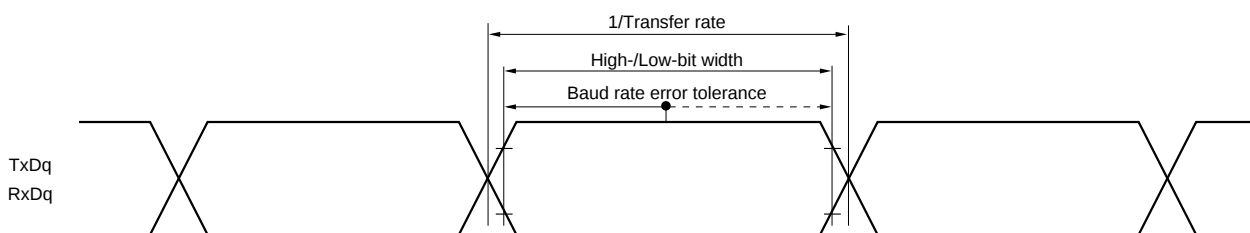
( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

| Parameter                       | Symbol | Conditions                                                                              | HS (high-speed main) Mode |             | LS (low-speed main) Mode |             | Unit |
|---------------------------------|--------|-----------------------------------------------------------------------------------------|---------------------------|-------------|--------------------------|-------------|------|
|                                 |        |                                                                                         | MIN.                      | TYP.        | MIN.                     | MAX.        |      |
| Transfer rate <sup>Note 1</sup> |        | $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$                                            |                           | $f_{MCK}/6$ |                          | $f_{MCK}/6$ | bps  |
|                                 |        | Theoretical value of the maximum transfer rate<br>$f_{MCK} = f_{CLK}$ <sup>Note 2</sup> |                           | 5.3         |                          | 1.3         | Mbps |

##### UART mode connection diagram (during communication at same potential)



##### UART mode bit width (during communication at same potential) (reference)



- Notes**
1. Transfer rate in the SNOOZE mode is 4800 bps only.
  2. The maximum operating frequencies of the CPU/peripheral hardware clock ( $f_{CLK}$ ) are:  
 HS (high-speed main) mode: 32 MHz ( $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ )  
 LS (low-speed main) mode: 8 MHz ( $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ).

- Remarks**
1. q: UART number (q = 0)
  2.  $f_{MCK}$ : Serial array unit operation clock frequency  
 (Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00, 01))

**(2) During communication at same potential (CSI mode) (master mode, SCKp... internal clock output)****(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V)**

| Parameter                                             | Symbol                              | Conditions                  | HS (high-speed main) Mode |      | LS (low-speed main) Mode  |      | Unit |
|-------------------------------------------------------|-------------------------------------|-----------------------------|---------------------------|------|---------------------------|------|------|
|                                                       |                                     |                             | MIN.                      | MAX. | MIN.                      | MAX. |      |
| SCKp cycle time                                       | t <sub>KCY1</sub>                   |                             | 83.3                      |      | 250                       |      | ns   |
| SCKp high-/low-level width                            | t <sub>KH1</sub> , t <sub>KL1</sub> |                             | t <sub>KCY1</sub> /2 - 10 |      | t <sub>KCY1</sub> /2 - 50 |      | ns   |
| Slp setup time (to SCKp↑) <sup>Note 1</sup>           | t <sub>SIK1</sub>                   |                             | 33                        |      | 110                       |      | ns   |
| Slp hold time (from SCKp↑) <sup>Note 1</sup>          | t <sub>KSI1</sub>                   |                             | 10                        |      | 10                        |      | ns   |
| Delay time from SCKp↓ to SOp output <sup>Note 2</sup> | t <sub>KSO1</sub>                   | C = 20 pF <sup>Note 3</sup> |                           | 10   |                           | 10   | ns   |

**Notes** 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp↓" and the Slp hold time becomes "from SCKp↓" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOp output becomes "from SCKp↑" when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

3. C is the load capacitance of the SCKp and SOp output lines.

**Remarks 1.** p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0)

2. f<sub>MCK</sub>: Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

**(3) During communication at same potential (CSI mode) (slave mode, SCKp... external clock input)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

| Parameter                                                         | Symbol                   | Conditions                           | HS (high-speed main)<br>Mode |                | LS (low-speed main)<br>Mode |                 | Unit |
|-------------------------------------------------------------------|--------------------------|--------------------------------------|------------------------------|----------------|-----------------------------|-----------------|------|
|                                                                   |                          |                                      | MIN.                         | MAX.           | MIN.                        | MAX.            |      |
| SCKp cycle time <sup>Note 4</sup>                                 | $t_{KCY2}$               | $16\text{ MHz} < f_{MCK}$            | $8/f_{MCK}$                  |                | -                           |                 | ns   |
|                                                                   |                          | $f_{MCK} \leq 16\text{ MHz}$         | $6/f_{MCK}$                  |                | $6/f_{MCK}$                 |                 | ns   |
| SCKp high-/low-level width                                        | $t_{KH2}$ ,<br>$t_{KL2}$ |                                      | $t_{KCY2}/2-8$               |                | $t_{KCY2}/2-8$              |                 | ns   |
| Slp setup time (to SCKp $\uparrow$ ) <sup>Note 1</sup>            | $t_{SIK2}$               |                                      | $1/f_{MCK}+20$               |                | $1/f_{MCK}+30$              |                 | ns   |
| Slp hold time (from SCKp $\uparrow$ ) <sup>Note 1</sup>           | $t_{KSI2}$               |                                      | $1/f_{MCK}+31$               |                | $1/f_{MCK}+31$              |                 | ns   |
| Delay time from SCKp $\downarrow$ to SOP output <sup>Note 2</sup> | $t_{KSO2}$               | $C = 30\text{ pF}$ <sup>Note 3</sup> |                              | $2/f_{MCK}+44$ |                             | $2/f_{MCK}+110$ | ns   |
| SSI00 setup time                                                  | $t_{SSIK}$               | DAPmn = 0                            | 120                          |                | 120                         |                 | ns   |
|                                                                   |                          | DAPmn = 1                            | $1/f_{MCK}+120$              |                | $1/f_{MCK}+120$             |                 | ns   |
| SSI00 hold time                                                   | $t_{KSSI}$               | DAPmn = 0                            | $1/f_{MCK}+120$              |                | $1/f_{MCK}+120$             |                 | ns   |
|                                                                   |                          | DAPmn = 1                            | 120                          |                | 120                         |                 | ns   |

**Notes** 1. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The Slp setup time becomes "to SCKp $\downarrow$ " and the Slp hold time becomes "from SCKp $\downarrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

2. When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1. The delay time to SOP output becomes "from SCKp $\uparrow$ " when DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.

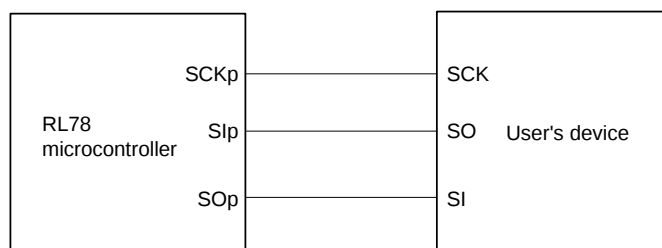
3. C is the load capacitance of the SOP output lines.

4. Transfer rate in the SNOOZE mode: MAX. 1 Mbps

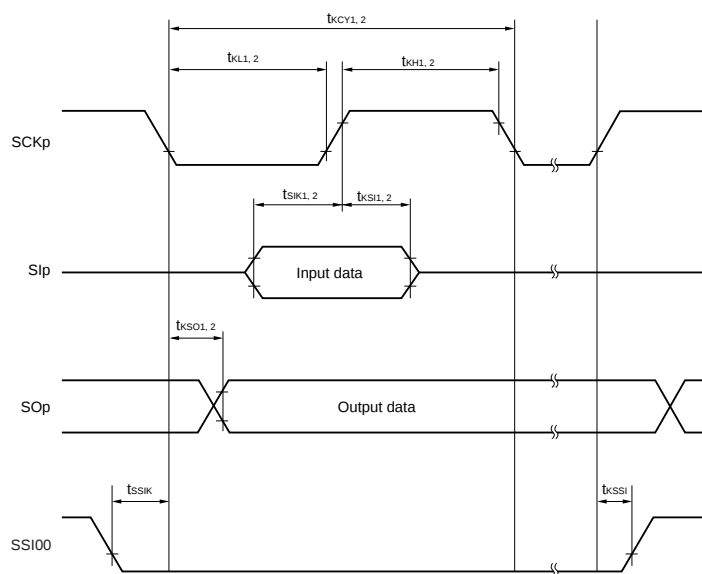
**Remarks** 1. p: CSI number (p = 00), m: Unit number (m = 0), n: Channel number (n = 0)

2.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number (mn = 00))

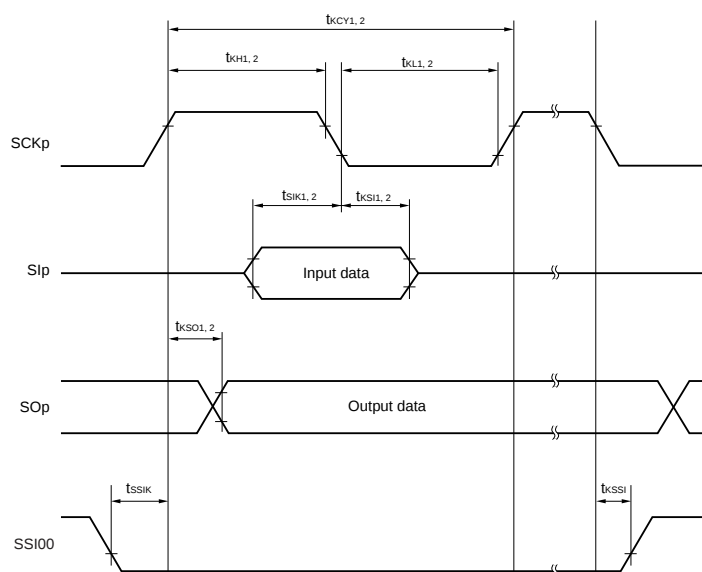
## CSI mode connection diagram (during communication at same potential)



CSI mode serial transfer timing (during communication at same potential)  
 (When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)



CSI mode serial transfer timing (during communication at same potential)  
 (When DAPmn = 0 and CKPmn = 1, or DAPmn = 1 and CKPmn = 0.)



**Remarks 1.** p: CSI number (p = 00)

**2.** m: Unit number, n: Channel number (mn = 00)

## 2.5.2 Serial interface IICA

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V)

| Parameter                                       | Symbol              | Conditions                                   | Standard Mode |      | Fast Mode |      | Fast Mode Plus |      | Unit |
|-------------------------------------------------|---------------------|----------------------------------------------|---------------|------|-----------|------|----------------|------|------|
|                                                 |                     |                                              | MIN.          | MAX. | MIN.      | MAX. | MIN.           | MAX. |      |
| SCLAn clock frequency                           | f <sub>SCL</sub>    | Fast mode plus:<br>f <sub>CLK</sub> ≥ 10 MHz |               |      |           |      | 0              | 1000 | kHz  |
|                                                 |                     | Fast mode:<br>f <sub>CLK</sub> ≥ 3.5 MHz     |               |      | 0         | 400  |                |      | kHz  |
|                                                 |                     | Normal mode:<br>f <sub>CLK</sub> ≥ 1 MHz     | 0             | 100  |           |      |                |      | kHz  |
| Setup time of restart condition                 | t <sub>SU:STA</sub> |                                              | 4.7           |      | 0.6       |      | 0.26           |      | μs   |
| Hold time <sup>Note 1</sup>                     | t <sub>HD:STA</sub> |                                              | 4.0           |      | 0.6       |      | 0.26           |      | μs   |
| Hold time when SCLAn = "L"                      | t <sub>LOW</sub>    |                                              | 4.7           |      | 1.3       |      | 0.5            |      | μs   |
| Hold time when SCLAn = "H"                      | t <sub>HIGH</sub>   |                                              | 4.0           |      | 0.6       |      | 0.26           |      | μs   |
| Data setup time (reception)                     | t <sub>SU:DAT</sub> |                                              | 250           |      | 100       |      | 50             |      | ns   |
| Data hold time (transmission) <sup>Note 2</sup> | t <sub>HD:DAT</sub> |                                              | 0             | 3.45 | 0         | 0.9  | 0              | 0.45 | μs   |
| Setup time of stop condition                    | t <sub>SU:STO</sub> |                                              | 4.0           |      | 0.6       |      | 0.26           |      | μs   |
| Bus-free time                                   | t <sub>BUF</sub>    |                                              | 4.7           |      | 1.3       |      | 0.5            |      | μs   |

- Notes**
1. The first clock pulse is generated after this period when the start/restart condition is detected.
  2. The maximum value (MAX.) of t<sub>HD:DAT</sub> is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

**Remarks 1.** The maximum value of C<sub>b</sub> (communication line capacitance) and the value of R<sub>b</sub> (communication line pull-up resistor) at that time in each mode are as follows.

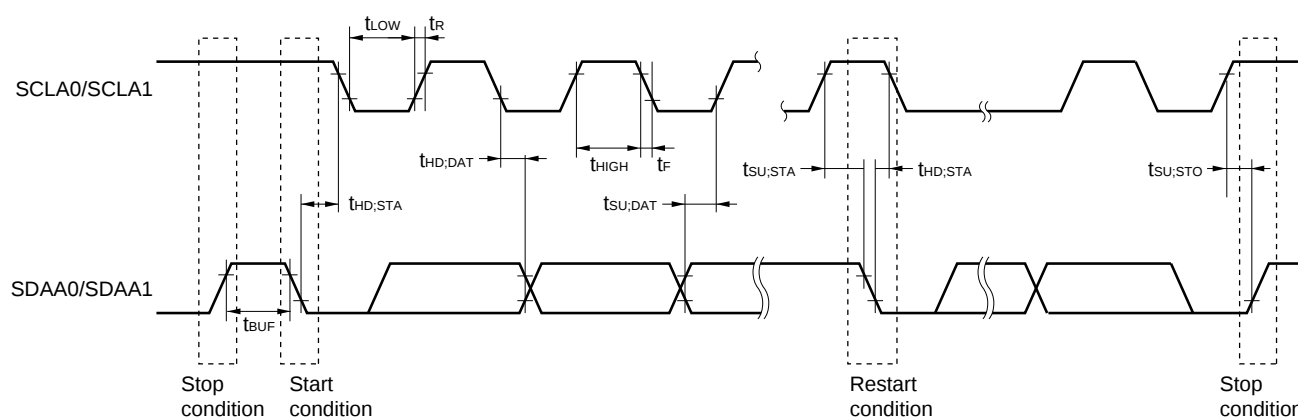
Standard mode: C<sub>b</sub> = 400 pF, R<sub>b</sub> = 2.7 kΩ

Fast mode: C<sub>b</sub> = 320 pF, R<sub>b</sub> = 1.1 kΩ

Fast mode plus: C<sub>b</sub> = 120 pF, R<sub>b</sub> = 1.1 kΩ

2. n = 0, 1

## IICA serial transfer timing



### 2.5.3 Dedicated Flash Memory Programmer Communication (UART)

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

| Parameter     | Symbol | Conditions | MIN.    | TYP. | MAX. | Unit |
|---------------|--------|------------|---------|------|------|------|
| Transfer rate |        |            | 115.2 k |      | 1 M  | bps  |

## 2.6 Analog Characteristics

### 2.6.1 A/D converter characteristics

#### Classification of A/D converter characteristics

| Reference Voltage<br>Input channel | Reference voltage (+) = $AV_{REFP}$<br>Reference voltage (-) = $AV_{REFM}$ | Reference voltage (+) = $V_{DD}$<br>Reference voltage (-) = $V_{SS}$ | Reference voltage (+) = $V_{BGR}$<br>Reference voltage (-) = $AV_{REFM}$ |
|------------------------------------|----------------------------------------------------------------------------|----------------------------------------------------------------------|--------------------------------------------------------------------------|
| ANI0 to ANI7                       | Refer to 2.6.1 (1)                                                         | Refer to 2.6.1 (2)                                                   | Refer to 2.6.1 (5)                                                       |
| ANI16                              | Refer to 2.6.1 (3)                                                         | Refer to 2.6.1 (4)                                                   |                                                                          |
| Internal reference voltage         | Refer to 2.6.1 (3)                                                         | Refer to 2.6.1 (4)                                                   | –                                                                        |
| Temperature sensor output voltage  |                                                                            |                                                                      |                                                                          |

(1) When  $AV_{REF}(+) = AV_{REFP}/ANI0$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 1$ ),  $AV_{REF}(-) = AV_{REFM}/ANI1$  ( $ADREFM = 1$ ), target ANI pin: ANI0 to ANI7

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $AV_{REFP}$ , Reference voltage (-) =  $AV_{REFM} = 0\text{ V}$ )

| Parameter                                      | Symbol      | Conditions                                                                                                           | MIN.  | TYP. | MAX.        | Unit          |
|------------------------------------------------|-------------|----------------------------------------------------------------------------------------------------------------------|-------|------|-------------|---------------|
| Resolution                                     | RES         |                                                                                                                      | 8     |      | 12          | bit           |
| Overall error <sup>Note 1</sup>                | AINL        | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 6.0$   | LSB           |
| Conversion time                                | $t_{CONV}$  | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            | 3.375 |      | 108         | $\mu\text{s}$ |
| Zero-scale error <sup>Notes 1, 2</sup>         | $E_{ZS}$    | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 0.10$  | %FSR          |
| Full-scale error <sup>Notes 1, 2</sup>         | $E_{FS}$    | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 0.10$  | %FSR          |
| Integral linearity error <sup>Note 1</sup>     | ILE         | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 2.5$   | LSB           |
| Differential linearity error <sup>Note 1</sup> | DLE         | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 1.5$   | LSB           |
| Reference voltage (+)                          | $AV_{REFP}$ |                                                                                                                      | 2.7   |      | $V_{DD}$    | V             |
| Reference voltage (-)                          | $AV_{REFM}$ |                                                                                                                      | -0.5  |      | 0.3         | V             |
| Analog input voltage                           | $V_{AIN}$   |                                                                                                                      | 0     |      | $AV_{REFP}$ | V             |
|                                                | $V_{BGR}$   | Select internal reference voltage output<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ , HS (high-speed main) mode | 1.38  | 1.45 | 1.5         | V             |

**Notes 1.** Excludes quantization error ( $\pm 1/2$  LSB).

**2.** This value is indicated as a ratio (%FSR) to the full-scale value.

(2) When  $AV_{REF}(+) = V_{DD}$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 0$ ),  $AV_{REF}(-) = V_{SS}$  ( $ADREFM = 0$ ), target ANI pin: ANI0 to ANI7

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $V_{SS}$ , Reference voltage (-) =  $V_{SS}$ )

| Parameter                                      | Symbol     | Conditions                                                                                                           | MIN.  | TYP. | MAX.        | Unit          |
|------------------------------------------------|------------|----------------------------------------------------------------------------------------------------------------------|-------|------|-------------|---------------|
| Resolution                                     | RES        |                                                                                                                      | 8     |      | 12          | bit           |
| Overall error <sup>Note 1</sup>                | AINL       | 10-bit resolution                                                                                                    |       |      | $\pm 7.0$   | LSB           |
| Conversion time                                | $t_{CONV}$ | 10-bit resolution                                                                                                    | 3.375 |      | 108         | $\mu\text{s}$ |
| Zero-scale error <sup>Notes 1, 2</sup>         | $E_{ZS}$   | 10-bit resolution                                                                                                    |       |      | $\pm 0.60$  | %FSR          |
| Full-scale error <sup>Notes 1, 2</sup>         | $E_{FS}$   | 10-bit resolution                                                                                                    |       |      | $\pm 0.60$  | %FSR          |
| Integral linearity error <sup>Note 1</sup>     | ILE        | 10-bit resolution                                                                                                    |       |      | $\pm 4.0$   | LSB           |
| Differential linearity error <sup>Note 1</sup> | DLE        | 10-bit resolution                                                                                                    |       |      | $\pm 2.0$   | LSB           |
| Analog input voltage                           | $V_{AIN}$  |                                                                                                                      | 0     |      | $AV_{REFP}$ | V             |
|                                                | $V_{BGR}$  | Select internal reference voltage output<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ , HS (high-speed main) mode | 1.38  | 1.45 | 1.5         | V             |

**Notes 1.** Excludes quantization error ( $\pm 1/2$  LSB).

**2.** This value is indicated as a ratio (%FSR) to the full-scale value.

(3) When  $AV_{REF}(+) = AV_{REFP}/ANI0$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 1$ ),  $AV_{REF}(-) = AV_{REFM}/ANI1$  ( $ADREFM = 1$ ), target ANI pin: ANI16, internal reference voltage, and temperature sensor output voltage

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $AV_{REFP}$ , Reference voltage (-) =  $AV_{REFM} = 0\text{ V}$ )

| Parameter                                      | Symbol      | Conditions                                                                                                           | MIN.  | TYP. | MAX.        | Unit          |
|------------------------------------------------|-------------|----------------------------------------------------------------------------------------------------------------------|-------|------|-------------|---------------|
| Resolution                                     | RES         |                                                                                                                      | 8     |      | 12          | bit           |
| Overall error <sup>Note 1</sup>                | AINL        | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 7.0$   | LSB           |
| Conversion time                                | $t_{CONV}$  | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            | 4.125 |      | 132         | $\mu\text{s}$ |
| Zero-scale error <sup>Notes 1, 2</sup>         | $E_{ZS}$    | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 0.10$  | %FSR          |
| Full-scale error <sup>Notes 1, 2</sup>         | $E_{FS}$    | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 0.10$  | %FSR          |
| Integral linearity error <sup>Note 1</sup>     | ILE         | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 3.0$   | LSB           |
| Differential linearity error <sup>Note 1</sup> | DLE         | 12-bit resolution<br>$AV_{REFP} = V_{DD}$                                                                            |       |      | $\pm 2.0$   | LSB           |
| Reference voltage (+)                          | $AV_{REFP}$ |                                                                                                                      | 2.7   |      | $V_{DD}$    | V             |
| Reference voltage (-)                          | $AV_{REFM}$ |                                                                                                                      | -0.5  |      | 0.3         | V             |
| Analog input voltage                           | $V_{AIN}$   |                                                                                                                      | 0     |      | $AV_{REFP}$ | V             |
|                                                | $V_{BGR}$   | Select internal reference voltage output<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ , HS (high-speed main) mode | 1.38  | 1.45 | 1.5         | V             |

**Notes 1.** Excludes quantization error ( $\pm 1/2$  LSB).

**2.** This value is indicated as a ratio (%FSR) to the full-scale value.

(4) When  $AV_{REF}(+) = V_{DD}$  ( $ADREFP1 = 0$ ,  $ADREFP0 = 0$ ),  $AV_{REF}(-) = V_{SS}$  ( $ADREFM = 0$ ), target ANI pin: ANI16, internal reference voltage, and temperature sensor output voltage

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $V_{DD}$ , Reference voltage (-) =  $V_{SS}$ )

| Parameter                                      | Symbol     | Conditions                                                                                                           | MIN.  | TYP. | MAX.       | Unit          |
|------------------------------------------------|------------|----------------------------------------------------------------------------------------------------------------------|-------|------|------------|---------------|
| Resolution                                     | RES        |                                                                                                                      | 8     |      | 12         | bit           |
| Overall error <sup>Note 1</sup>                | AINL       | 10-bit resolution                                                                                                    |       |      | $\pm 7.0$  | LSB           |
| Conversion time                                | $t_{CONV}$ | 10-bit resolution                                                                                                    | 4.125 |      | 132        | $\mu\text{s}$ |
| Zero-scale error <sup>Notes 1, 2</sup>         | $E_{ZS}$   | 10-bit resolution                                                                                                    |       |      | $\pm 0.60$ | %FSR          |
| Full-scale error <sup>Notes 1, 2</sup>         | $E_{FS}$   | 10-bit resolution                                                                                                    |       |      | $\pm 0.60$ | %FSR          |
| Integral linearity error <sup>Note 1</sup>     | ILE        | 10-bit resolution                                                                                                    |       |      | $\pm 4.0$  | LSB           |
| Differential linearity error <sup>Note 1</sup> | DLE        | 10-bit resolution                                                                                                    |       |      | $\pm 2.5$  | LSB           |
| Analog input voltage                           | $V_{AIN}$  |                                                                                                                      | 0     |      | $V_{DD}$   | V             |
|                                                | $V_{BGR}$  | Select internal reference voltage output<br>$2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ , HS (high-speed main) mode | 1.38  | 1.45 | 1.5        | V             |

**Notes 1.** Excludes quantization error ( $\pm 1/2$  LSB).

**2.** This value is indicated as a ratio (%FSR) to the full-scale value.

(5) When  $AV_{REF}(+) = \text{Internal reference voltage}$  ( $ADREFP1 = 1$ ,  $ADREFP0 = 0$ ),  $AV_{REF}(-) = AV_{REFM}/ANI1$  ( $ADREFM = 1$ ), target ANI pin: ANI0 to ANI7, ANI16

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , Reference voltage (+) =  $V_{BGR}$ , Reference voltage (-) =  $AV_{REFM} = 0\text{ V}$ , HS (high-speed main) mode)

| Parameter                                      | Symbol     | Conditions       | MIN. | TYP. | MAX.       | Unit          |
|------------------------------------------------|------------|------------------|------|------|------------|---------------|
| Resolution                                     | RES        |                  | 8    |      |            | bit           |
| Conversion time                                | $t_{CONV}$ | 8-bit resolution | 16   |      | 108        | $\mu\text{s}$ |
| Zero-scale error <sup>Notes 1, 2</sup>         | $E_{ZS}$   | 8-bit resolution |      |      | $\pm 1.60$ | %FSR          |
| Integral linearity error <sup>Note 1</sup>     | ILE        | 8-bit resolution |      |      | $\pm 2.5$  | LSB           |
| Differential linearity error <sup>Note 1</sup> | DLE        | 8-bit resolution |      |      | $\pm 2.5$  | LSB           |
| Analog input voltage                           | $V_{AIN}$  |                  | 0    |      | $V_{BGR}$  | V             |

**Notes 1.** Excludes quantization error ( $\pm 1/2$  LSB).

**2.** This value is indicated as a ratio (%FSR) to the full-scale value.

## 2.6.2 Temperature sensor/internal reference voltage characteristics

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V, HS (high-speed main) mode)

| Parameter                         | Symbol              | Conditions                                         | MIN. | TYP. | MAX. | Unit  |
|-----------------------------------|---------------------|----------------------------------------------------|------|------|------|-------|
| Temperature sensor output voltage | V <sub>TMP25</sub>  | Setting ADS register = 80H, T <sub>A</sub> = +25°C |      | 1.05 |      | V     |
| Internal reference voltage        | V <sub>BGR</sub>    | Setting ADS register = 81H                         | 1.38 | 1.45 | 1.5  | V     |
| Temperature coefficient           | F <sub>VTMP25</sub> | Temperature sensor that depends on the temperature |      | -3.6 |      | mV/°C |
| Operation stabilization wait time | t <sub>AMP</sub>    |                                                    | 5    |      |      | μs    |

## 2.6.3 D/A converter

(T<sub>A</sub> = -40 to +85°C, 2.7 V ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V)

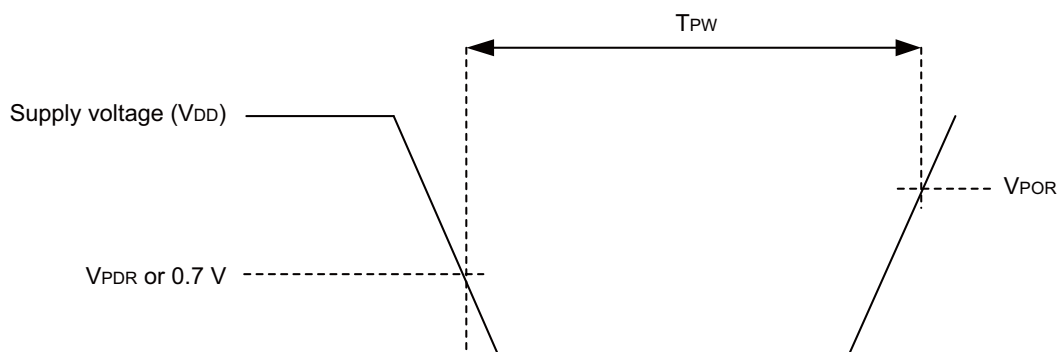
| Parameter             | Symbol           | Conditions                                                                                                     | MIN. | TYP. | MAX.  | Unit |
|-----------------------|------------------|----------------------------------------------------------------------------------------------------------------|------|------|-------|------|
| Resolution            | R <sub>ES</sub>  |                                                                                                                |      |      | 10    | bit  |
| Overall error         | A <sub>INL</sub> | Load current = 0 mA,<br>0.2 V ≤ output voltage ≤ V <sub>DD</sub> - 0.2 V                                       |      | ±2.0 | ±4.0  | LSB  |
|                       |                  | Load = 2.5 kΩ,<br>0.2 V ≤ output voltage ≤ V <sub>DD</sub> - 0.2 V                                             |      | ±5.0 | ±10.0 | LSB  |
| Settling time         | t <sub>SET</sub> | R <sub>load</sub> = 47 kΩ, C <sub>load</sub> = 20 pF                                                           |      |      | 10    | μs   |
| D/A output resistance | R <sub>O</sub>   | Per channel<br>Output voltage = 0 V to 0.2 V or<br>Output voltage = V <sub>DD</sub> - 0.2 V to V <sub>DD</sub> |      | 40   | 60    | Ω    |
|                       |                  | Per channel<br>Output voltage = 0.2 V to V <sub>DD</sub> - 0.2 V                                               |      | 8    | 12    | Ω    |

## 2.6.4 POR circuit characteristics

(T<sub>A</sub> = -40 to +85°C, V<sub>SS</sub> = 0 V)

| Parameter                           | Symbol           | Conditions             | MIN. | TYP. | MAX. | Unit |
|-------------------------------------|------------------|------------------------|------|------|------|------|
| Detection voltage                   | V <sub>POR</sub> | Power supply rise time | 1.47 | 1.51 | 1.55 | V    |
|                                     | V <sub>PDR</sub> | Power supply fall time | 1.46 | 1.50 | 1.54 | V    |
| Minimum pulse width <sup>Note</sup> | T <sub>PW</sub>  |                        | 300  |      |      | μs   |

**Note** Minimum time required for a POR reset when V<sub>DD</sub> exceeds below V<sub>PDR</sub>. This is also the minimum time required for a POR reset from when V<sub>DD</sub> exceeds below 0.7 V to when V<sub>DD</sub> exceeds V<sub>POR</sub> while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



## 2.6.5 LVD circuit characteristics

## LVD Detection Voltage of Reset Mode and Interrupt Mode

(T<sub>A</sub> = -40 to +85°C, V<sub>PDR</sub> ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V)

| Parameter            | Symbol            | Conditions             | MIN. | TYP. | MAX. | Unit |
|----------------------|-------------------|------------------------|------|------|------|------|
| Detection voltage    | V <sub>LVD2</sub> | Power supply rise time | 3.07 | 3.13 | 3.19 | V    |
|                      |                   | Power supply fall time | 3.00 | 3.06 | 3.12 | V    |
|                      | V <sub>LVD3</sub> | Power supply rise time | 2.96 | 3.02 | 3.08 | V    |
|                      |                   | Power supply fall time | 2.90 | 2.96 | 3.02 | V    |
|                      | V <sub>LVD4</sub> | Power supply rise time | 2.86 | 2.92 | 2.97 | V    |
|                      |                   | Power supply fall time | 2.80 | 2.86 | 2.91 | V    |
|                      | V <sub>LVD5</sub> | Power supply rise time | 2.76 | 2.81 | 2.87 | V    |
|                      |                   | Power supply fall time | 2.70 | 2.75 | 2.81 | V    |
| Minimum pulse width  | t <sub>LW</sub>   |                        | 300  |      |      | μs   |
| Detection delay time |                   |                        |      |      | 300  | μs   |

## LVD Detection Voltage of Interrupt &amp; Reset Mode

(T<sub>A</sub> = -40 to +85°C, V<sub>PDR</sub> ≤ V<sub>DD</sub> ≤ 3.6 V, V<sub>SS</sub> = 0 V)

| Parameter         | Symbol            | Conditions                                                                                 |                              | MIN. | TYP. | MAX. | Unit |
|-------------------|-------------------|--------------------------------------------------------------------------------------------|------------------------------|------|------|------|------|
| Detection voltage | V <sub>LVD5</sub> | V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 1, falling reset voltage |                              | 2.70 | 2.75 | 2.81 | V    |
|                   | V <sub>LVD4</sub> | LVIS1, LVIS0 = 1, 0                                                                        | Rising release reset voltage | 2.86 | 2.92 | 2.97 | V    |
|                   |                   |                                                                                            | Falling interrupt voltage    | 2.80 | 2.86 | 2.91 | V    |
|                   | V <sub>LVD3</sub> | LVIS1, LVIS0 = 0, 1                                                                        | Rising release reset voltage | 2.96 | 3.02 | 3.08 | V    |
|                   |                   |                                                                                            | Falling interrupt voltage    | 2.90 | 2.96 | 3.02 | V    |

## 2.6.6 Power supply voltage rising slope characteristics

(T<sub>A</sub> = -40 to +85°C, V<sub>SS</sub> = 0 V)

| Parameter                         | Symbol           | Conditions | MIN. | TYP. | MAX. | Unit |
|-----------------------------------|------------------|------------|------|------|------|------|
| Power supply voltage rising slope | S <sub>VDD</sub> |            |      |      | 54   | V/ms |

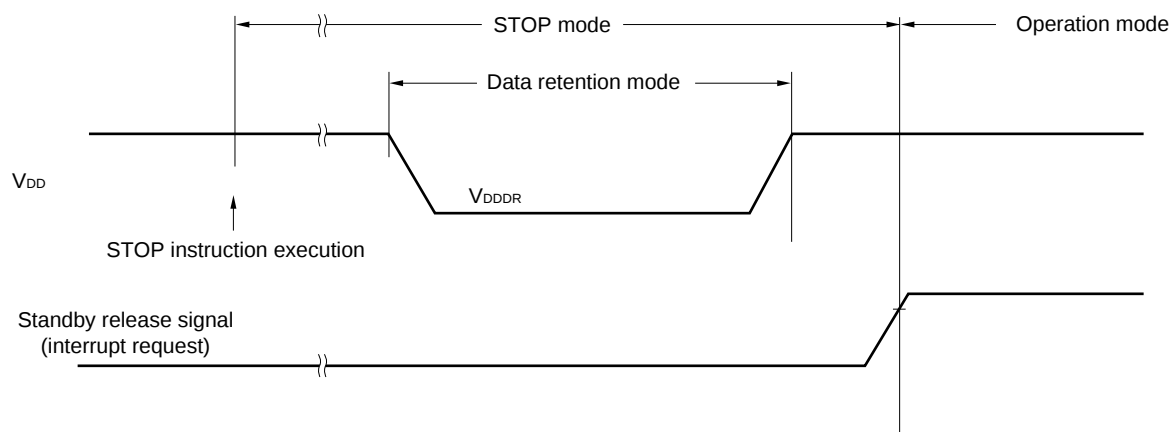
**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until V<sub>DD</sub> reaches the operating voltage range shown in 2.4 AC Characteristics.

## 2.7 RAM data retention characteristics

( $T_A = -40$  to  $+85^{\circ}\text{C}$ ,  $V_{SS} = 0\text{ V}$ )

| Parameter                     | Symbol     | Conditions | MIN.                 | TYP. | MAX. | Unit |
|-------------------------------|------------|------------|----------------------|------|------|------|
| Data retention supply voltage | $V_{DDDR}$ |            | 1.46 <sup>Note</sup> |      | 3.6  | V    |

**Note** The value depends on the POR detection voltage. When the voltage drops, the data is retained before a POR reset is effected, but data is not retained when a POR reset is effected.



## 2.8 Flash Memory Programming Characteristics

( $T_A = -40$  to  $+85^{\circ}\text{C}$ ,  $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

| Parameter                                                    | Symbol     | Conditions                                          | MIN.       | TYP.      | MAX. | Unit               |
|--------------------------------------------------------------|------------|-----------------------------------------------------|------------|-----------|------|--------------------|
| System clock frequency                                       | $f_{CLK}$  | $2.7\text{ V} \leq V_{DD} \leq 3.6\text{ V}$        | 1          |           | 32   | MHz                |
| Number of code flash rewrites<br><small>Note 1, 2, 3</small> | $C_{erwr}$ | Retained for 20 years<br>$T_A = 85^{\circ}\text{C}$ | 1,000      |           |      | Times              |
| Number of data flash rewrites<br><small>Note 1, 2, 3</small> |            | Retained for 1 years<br>$T_A = 25^{\circ}\text{C}$  |            | 1,000,000 |      |                    |
|                                                              |            | Retained for 5 years<br>$T_A = 85^{\circ}\text{C}$  | 100,000    |           |      |                    |
| Operating ambient temperature                                |            | In flash memory programming mode                    | 0 to +40   |           |      | $^{\circ}\text{C}$ |
|                                                              |            | In the self-programming mode                        | -40 to +85 |           |      | $^{\circ}\text{C}$ |

**Notes** 1. 1 erase + 1 write after the erase is regarded as 1 rewrite.

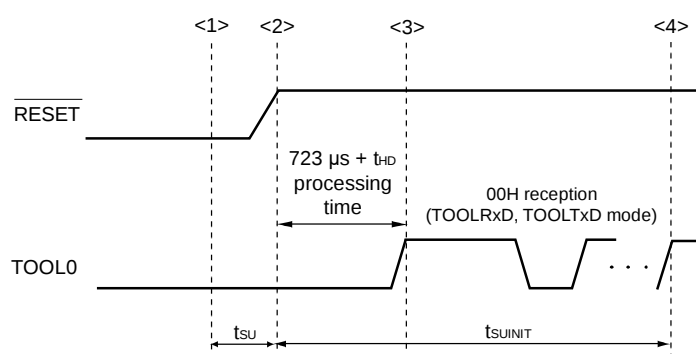
The retaining years are until next rewrite after the rewrite.

2. When using flash memory programmer and Renesas Electronics self programming library

3. These are the characteristics of the flash memory and the results obtained from reliability testing by Renesas Electronics Corporation.

## 2.9 Timing of Entry to Flash Memory Programming Modes

| Parameter                                                                                                                                                     | Symbol             | Conditions                                                 | MIN. | TYP. | MAX. | Unit          |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|------------------------------------------------------------|------|------|------|---------------|
| How long from when an external reset ends until the initial communication settings are specified                                                              | $t_{\text{SUNIT}}$ | POR and LVD reset must end before the external reset ends. |      |      | 100  | ms            |
| How long from when the TOOL0 pin is placed at the low level until an external reset ends                                                                      | $t_{\text{SU}}$    | POR and LVD reset must end before the external reset ends. | 10   |      |      | $\mu\text{s}$ |
| How long the TOOL0 pin must be kept at the low level after an external reset ends (excluding the processing time of the firmware to control the flash memory) | $t_{\text{HD}}$    | POR and LVD reset must end before the external reset ends. | 1    |      |      | ms            |



- <1> The low level is input to the TOOL0 pin.
- <2> The external reset ends (POR and LVD reset must end before the external reset ends.).
- <3> The TOOL0 pin is set to the high level.
- <4> Setting of the flash memory programming mode by UART reception and complete the baud rate setting.

**Remark**  $t_{\text{SUNIT}}$ : The segment shows that it is necessary to finish specifying the initial communication settings within 100 ms from when the resets end.

$t_{\text{SU}}$ : How long from when the TOOL0 pin is placed at the low level until an external reset ends (MIN. 10  $\mu\text{s}$ )

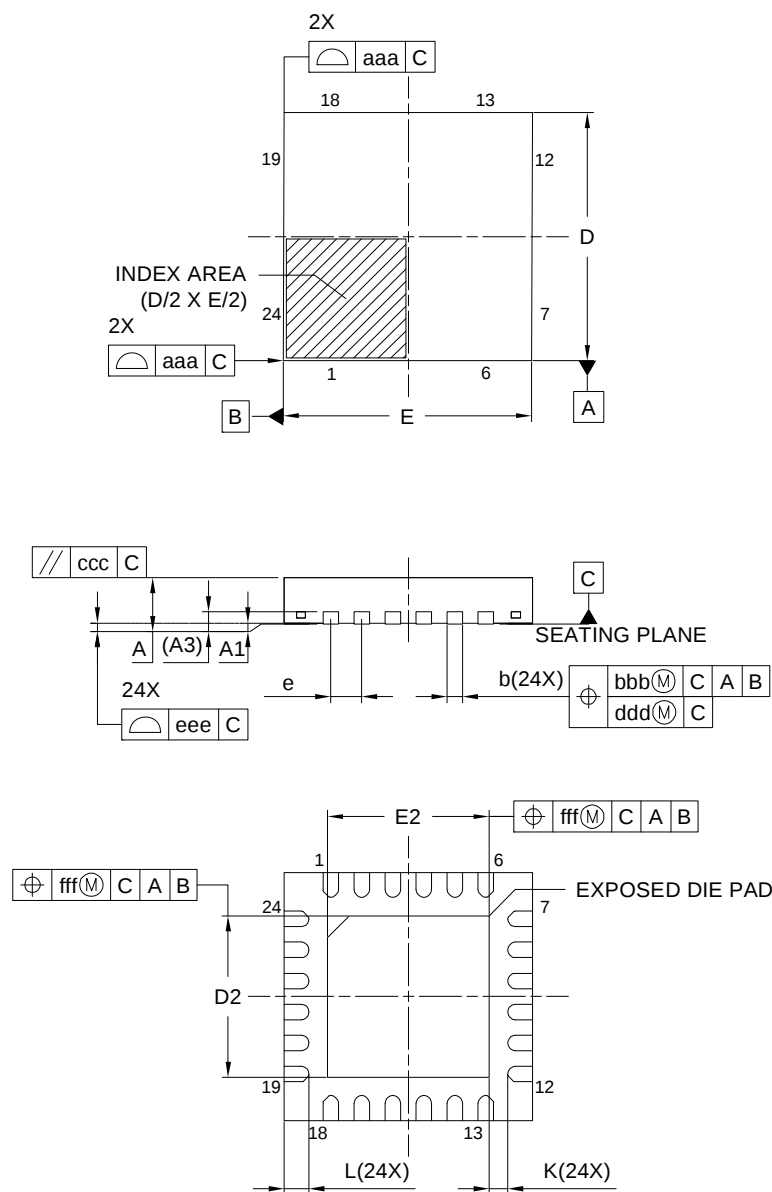
$t_{\text{HD}}$ : How long to keep the TOOL0 pin at the low level from when the external and internal resets end (except software processing time)

### 3. PACKAGE DRAWINGS

#### 3.1 24-pin Products

R5F11Z7AANA, R5F11Z7ADNA

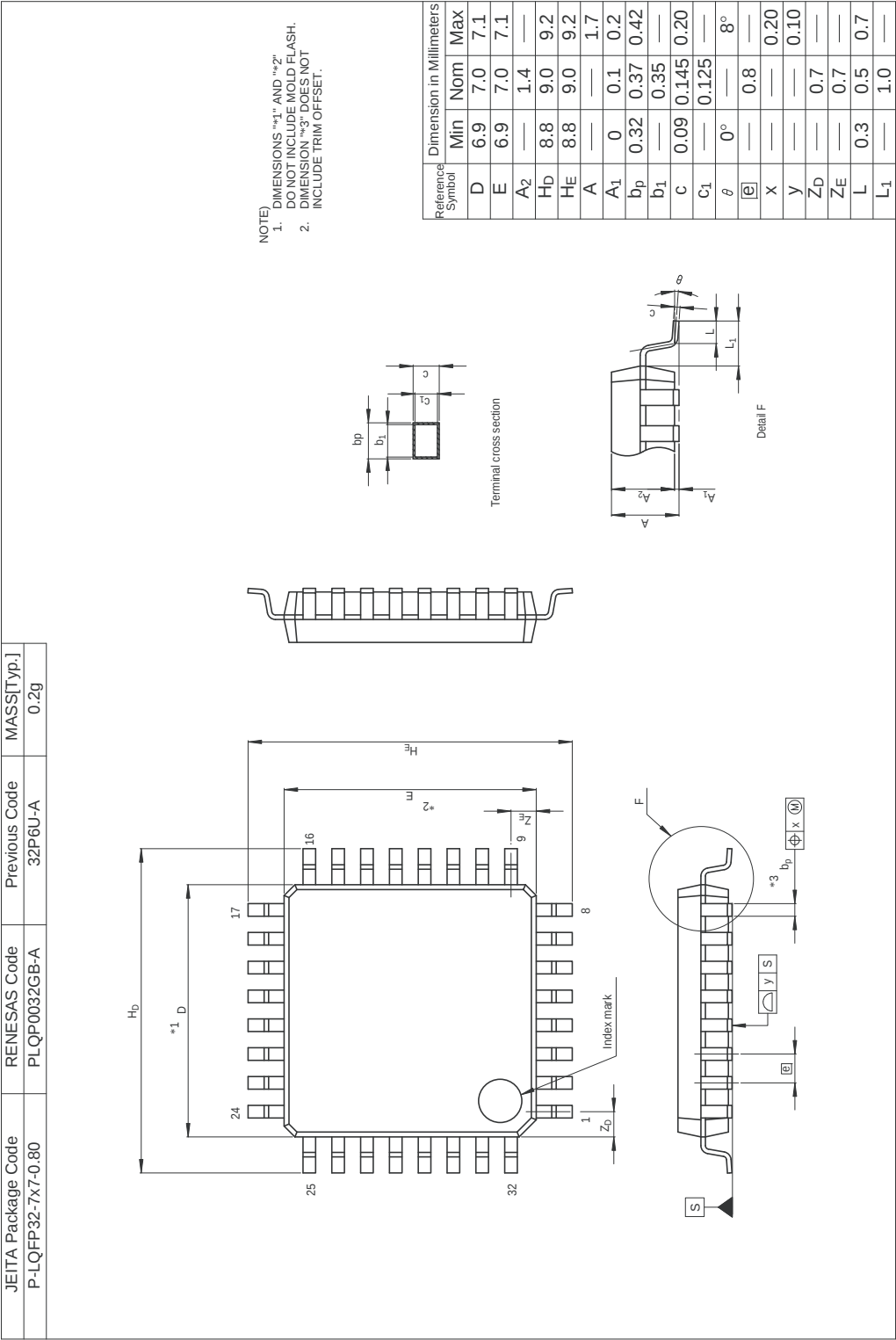
| JEITA Package code  | RENESAS code | MASS(TYP.)[g] |
|---------------------|--------------|---------------|
| P-HWQFN024-4x4-0.50 | PWQN0024KF-A | 0.04          |



| Reference Symbol | Dimension in Millimeters |      |      |
|------------------|--------------------------|------|------|
|                  | Min.                     | Nom. | Max. |
| A                | -                        | -    | 0.80 |
| A1               | 0.00                     | 0.02 | 0.05 |
| A3               | 0.203 REF.               |      |      |
| b                | 0.18                     | 0.25 | 0.30 |
| D                | 4.00 BSC                 |      |      |
| E                | 4.00 BSC                 |      |      |
| e                | 0.50 BSC                 |      |      |
| L                | 0.35                     | 0.40 | 0.45 |
| K                | 0.20                     | -    | -    |
| D2               | 2.55                     | 2.60 | 2.65 |
| E2               | 2.55                     | 2.60 | 2.65 |
| aaa              | 0.15                     |      |      |
| bbb              | 0.10                     |      |      |
| ccc              | 0.10                     |      |      |
| ddd              | 0.05                     |      |      |
| eee              | 0.08                     |      |      |
| fff              | 0.10                     |      |      |

3.2 32-pin Products

R5F11ZBAAFP, R5F11ZBADFP



|                         |                           |
|-------------------------|---------------------------|
| <b>Revision History</b> | <b>RL78/G1P Datasheet</b> |
|-------------------------|---------------------------|

| Rev. | Date         | Description |                      |
|------|--------------|-------------|----------------------|
|      |              | Page        | Summary              |
| 1.00 | Nov 29, 2019 | —           | First edition issued |

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# General Precautions in the Handling of Microprocessing Unit and Microcontroller Unit Products

The following usage notes are applicable to all Microprocessing unit and Microcontroller unit products from Renesas. For detailed usage notes on the products covered by this document, refer to the relevant sections of the document as well as any technical updates that have been issued for the products.

## 1. Precaution against Electrostatic Discharge (ESD)

A strong electrical field, when exposed to a CMOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop the generation of static electricity as much as possible, and quickly dissipate it when it occurs. Environmental control must be adequate. When it is dry, a humidifier should be used. This is recommended to avoid using insulators that can easily build up static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work benches and floors must be grounded. The operator must also be grounded using a wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions must be taken for printed circuit boards with mounted semiconductor devices.

## 2. Processing at power-on

The state of the product is undefined at the time when power is supplied. The states of internal circuits in the LSI are indeterminate and the states of register settings and pins are undefined at the time when power is supplied. In a finished product where the reset signal is applied to the external reset pin, the states of pins are not guaranteed from the time when power is supplied until the reset process is completed. In a similar way, the states of pins in a product that is reset by an on-chip power-on reset function are not guaranteed from the time when power is supplied until the power reaches the level at which resetting is specified.

## 3. Input of signal during power-off state

Do not input signals or an I/O pull-up power supply while the device is powered off. The current injection that results from input of such a signal or I/O pull-up power supply may cause malfunction and the abnormal current that passes in the device at this time may cause degradation of internal elements. Follow the guideline for input signal during power-off state as described in your product documentation.

## 4. Handling of unused pins

Handle unused pins in accordance with the directions given under handling of unused pins in the manual. The input pins of CMOS products are generally in the high-impedance state. In operation with an unused pin in the open-circuit state, extra electromagnetic noise is induced in the vicinity of the LSI, an associated shoot-through current flows internally, and malfunctions occur due to the false recognition of the pin state as an input signal become possible.

## 5. Clock signals

After applying a reset, only release the reset line after the operating clock signal becomes stable. When switching the clock signal during program execution, wait until the target clock signal is stabilized. When the clock signal is generated with an external resonator or from an external oscillator during a reset, ensure that the reset line is only released after full stabilization of the clock signal. Additionally, when switching to a clock signal produced with an external resonator or by an external oscillator while program execution is in progress, wait until the target clock signal is stable.

## 6. Voltage application waveform at input pin

Waveform distortion due to input noise or a reflected wave may cause malfunction. If the input of the CMOS device stays in the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.) due to noise, for example, the device may malfunction. Take care to prevent chattering noise from entering the device when the input level is fixed, and also in the transition period when the input level passes through the area between  $V_{IL}$  (Max.) and  $V_{IH}$  (Min.).

## 7. Prohibition of access to reserved addresses

Access to reserved addresses is prohibited. The reserved addresses are provided for possible future expansion of functions. Do not access these addresses as the correct operation of the LSI is not guaranteed.

## 8. Differences between products

Before changing from one product to another, for example to a product with a different part number, confirm that the change will not lead to problems. The characteristics of a microprocessing unit or microcontroller unit products in the same group but having a different part number might differ in terms of internal memory capacity, layout pattern, and other factors, which can affect the ranges of electrical characteristics, such as characteristic values, operating margins, immunity to noise, and amount of radiated noise. When changing to a product with a different part number, implement a system-evaluation test for the given product.

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TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

**Renesas Electronics America Inc.**  
1001 Murphy Ranch Road, Milpitas, CA 95035, U.S.A.  
Tel: +1-408-432-8888, Fax: +1-408-434-5351

**Renesas Electronics Canada Limited**  
9251 Yonge Street, Suite 8309 Richmond Hill, Ontario Canada L4C 9T3  
Tel: +1-905-237-2004

**Renesas Electronics Europe GmbH**  
Arcadiastrasse 10, 40472 Düsseldorf, Germany  
Tel: +49-211-6503-0, Fax: +49-211-6503-1327

**Renesas Electronics (China) Co., Ltd.**  
Room 101-T01, Floor 1, Building 7, Yard No. 7, 8th Street, Shangdi, Haidian District, Beijing 100085, China  
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

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Unit 301, Tower A, Central Towers, 555 Langao Road, Putuo District, Shanghai 200333, China  
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

**Renesas Electronics Hong Kong Limited**  
Unit 1601-1611, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong  
Tel: +852-2265-6688, Fax: +852 2886-9022

**Renesas Electronics Taiwan Co., Ltd.**  
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Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

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